

Emerging Areas in Photoelectron Spectroscopy (you can teach an old spectrometer new tricks)

K. Xerxes Steirer

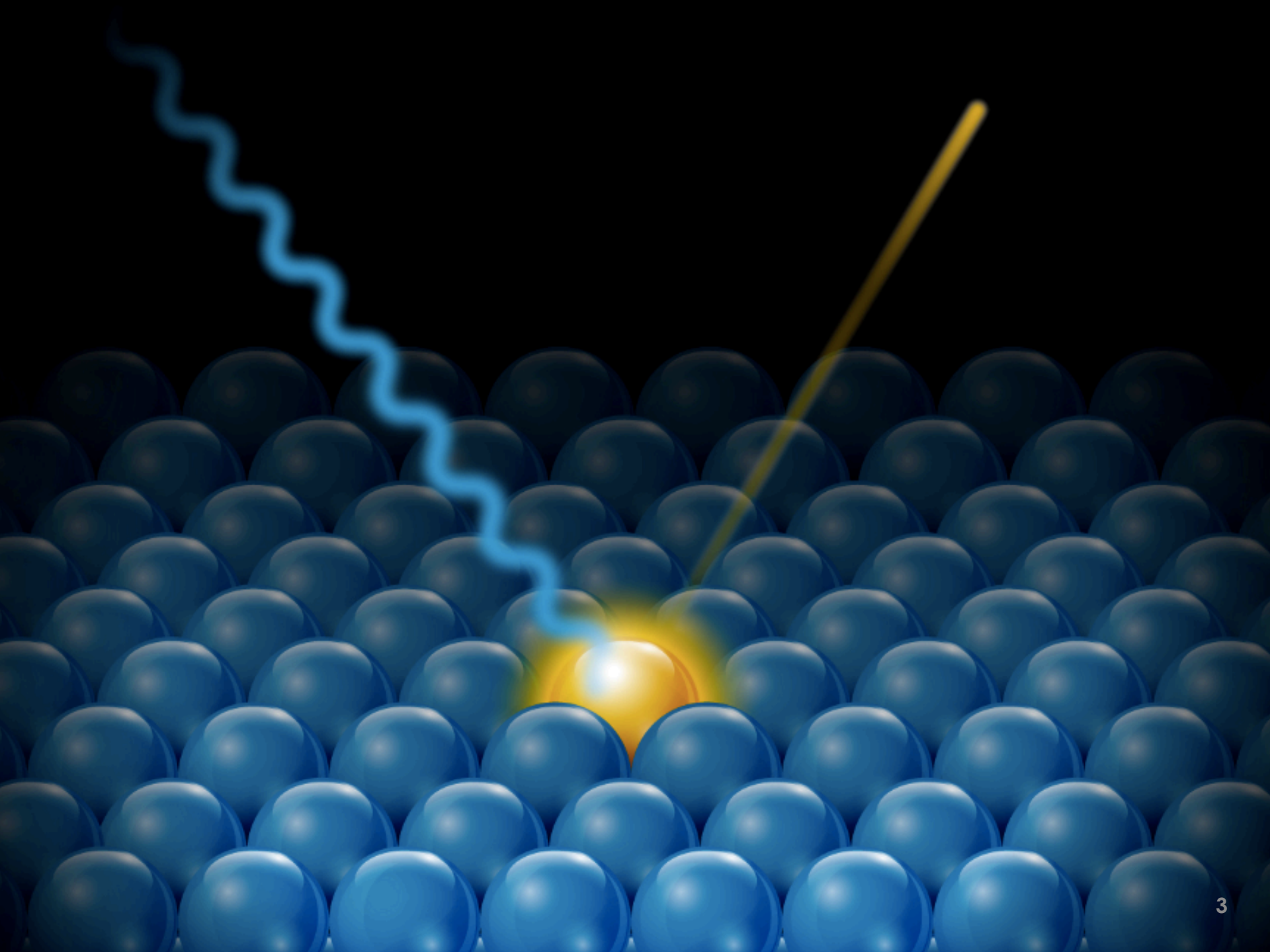
Research Assistant Professor of Applied Physics
Colorado School of Mines

What I Won't Talk About

- Standing Wave PES
- HAXPES – Hard X-rays
- Res-PES
- 2-PPE
- Spin resolved PES
- NEXAFS, XANES, variable energy PES or other beamline techniques
- The election

What I Will Talk About

- Photoelectric Effect
- XPS & UPS
- Apparatus
- Full spectral analysis
- Example Studies
 - Dipoles
 - NP interfaces
 - X-ray induced degradation
- New Areas in PES



Early Photoelectric Discovery

- 1887 – Hertz
- Hallwachs – showed UV increases positive charge to metal
- 1899 – Lenard demonstrated that the increasing charge is emission of electrons and that their velocity is independent of light intensity, depending rather on energy – disagreed with prevailing concepts
- Photoelectric effect – 1905
- Verified by Millikan and students
- “Einstein’s Law has become the basis of quantitative photo-chemistry in the same way as Faraday’s Law is the basis of electro-chemistry.”

• From Nobel Lectures, Physics 1901-1921, Elsevier Publishing Company, Amsterdam, 1967

• https://en.wikipedia.org/wiki/Photoelectric_effect

The Nobel Prize in Physics 1921



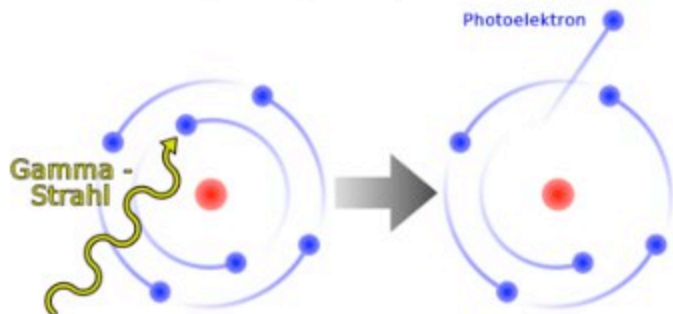
Albert Einstein
Prize share: 1/1

The Nobel Prize in Physics 1921 was awarded to Albert Einstein *“for his services to Theoretical Physics, and especially for his discovery of the law of the photoelectric effect”*.

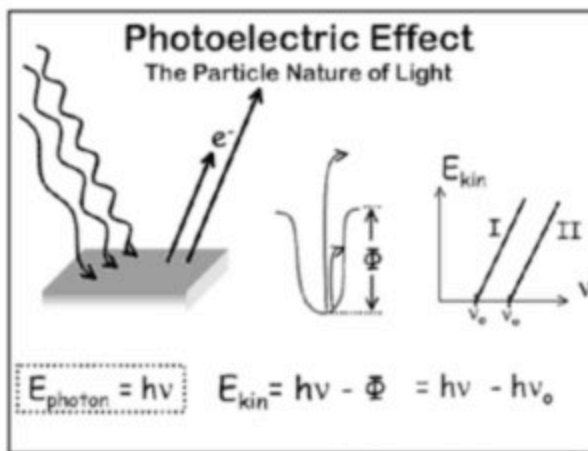
• <http://einsteinpapers.press.princeton.edu/vol2-trans/100?ajax>

E10

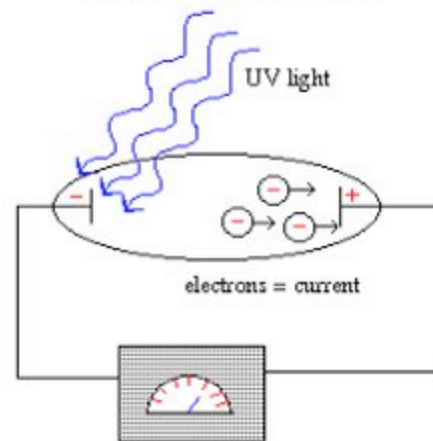
Photoelectric Effect



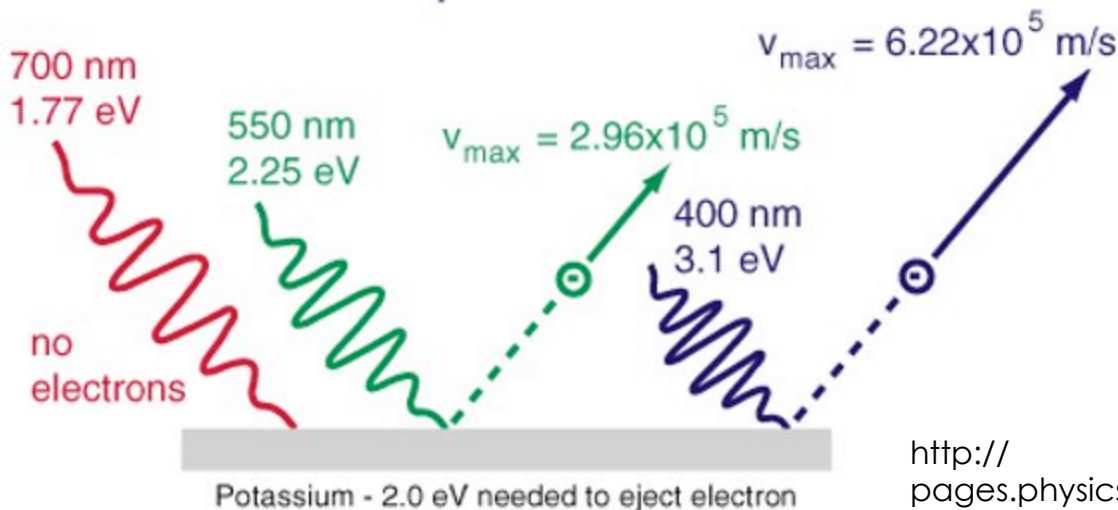
$$E_{\text{photon}} = h\nu$$



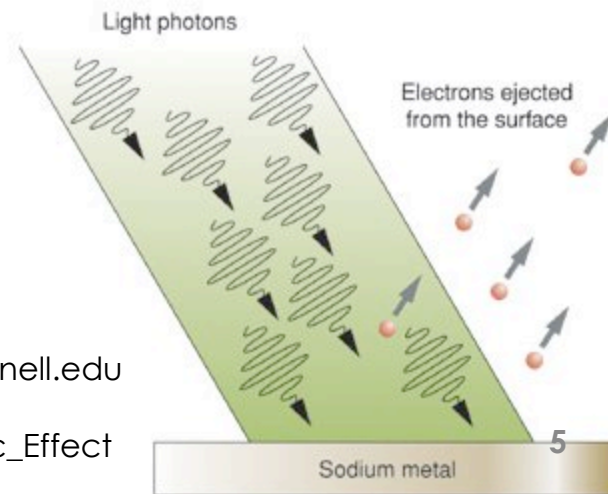
Photoelectric Effect



photon = wave particle of light



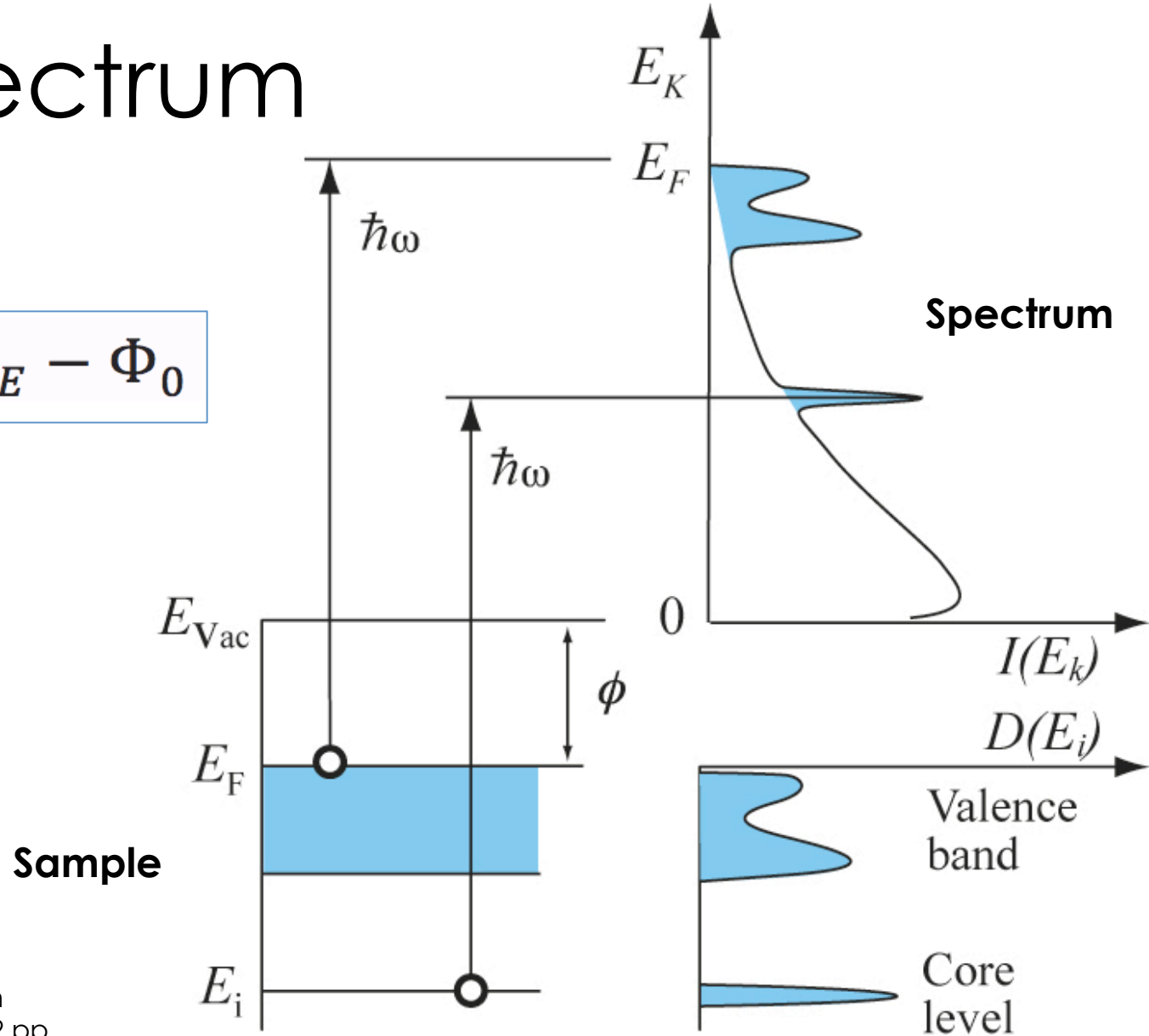
Photoelectric effect



<http://pages.physics.cornell.edu/p510/>
E-10_Photoelectric_Effect

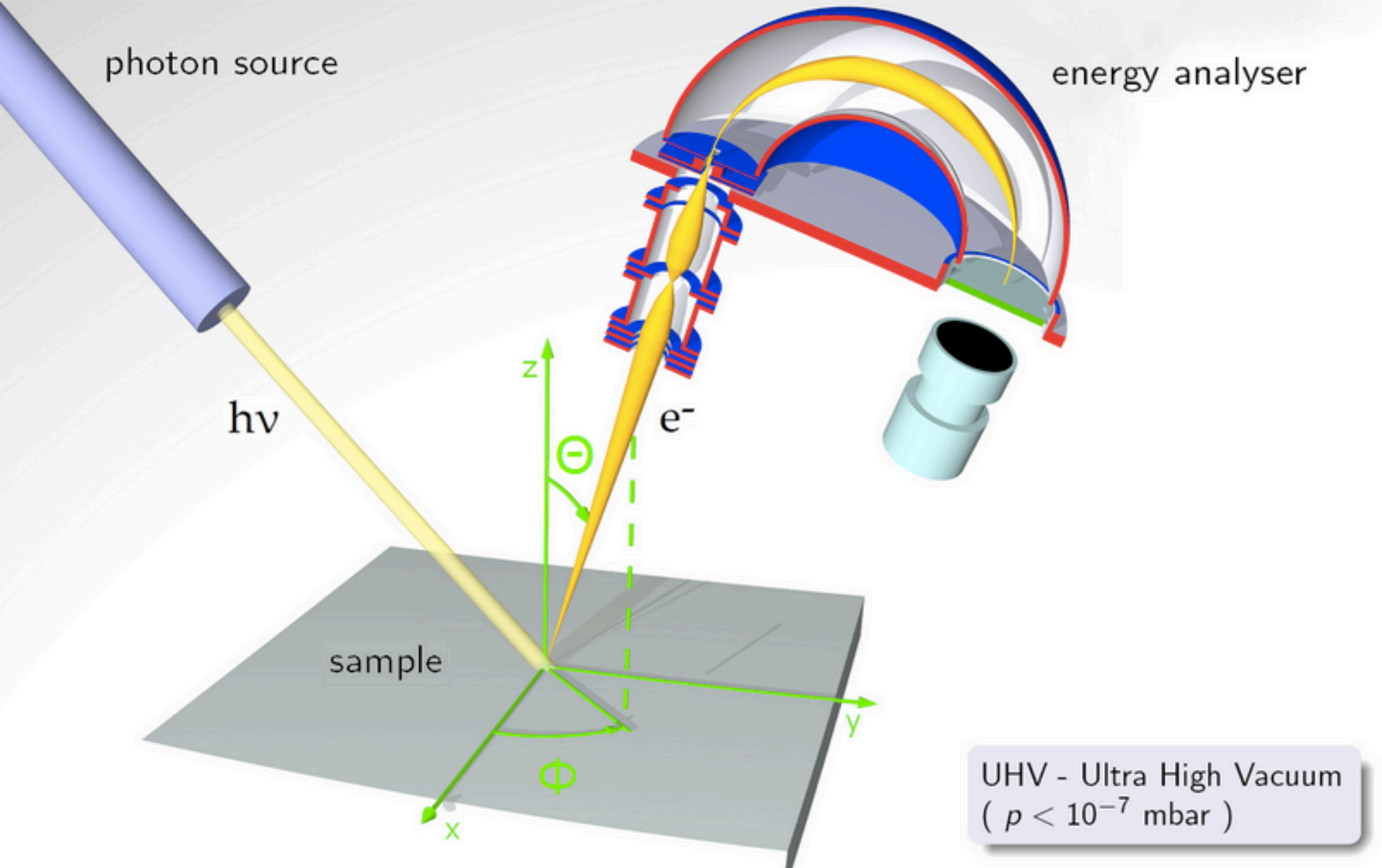
PES Spectrum

$$E_{KE} = h\nu - E_{BE} - \Phi_0$$



Oura K. et al. Surface Science: An Introduction // Springer, 2010 - 452 pp.

<http://eng.thesaurus.rusnano.com/wiki/article1915>

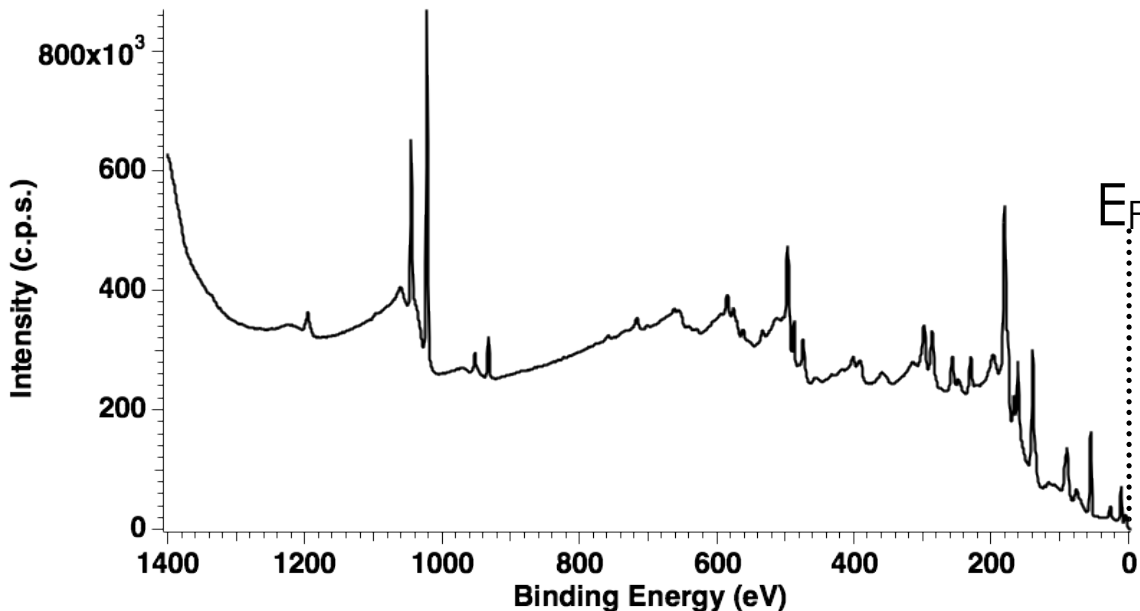
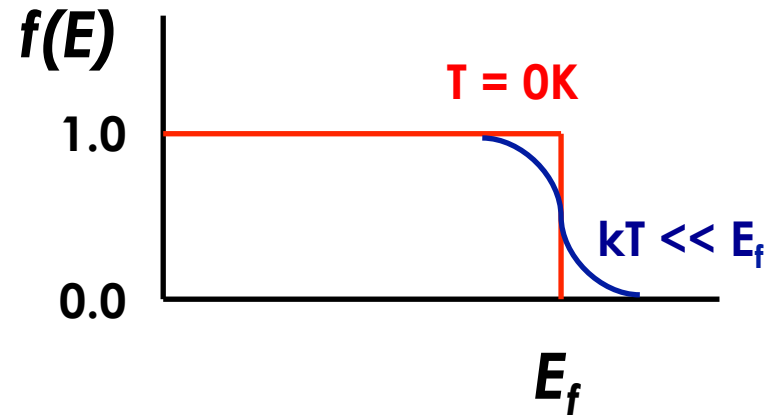


1 mbar = 0.75 torr

<https://www.khanacademy.org/science/chemistry/electronic-structure-of-atoms/electron-configurations-jay-sal/a/photoelectron-spectroscopy>

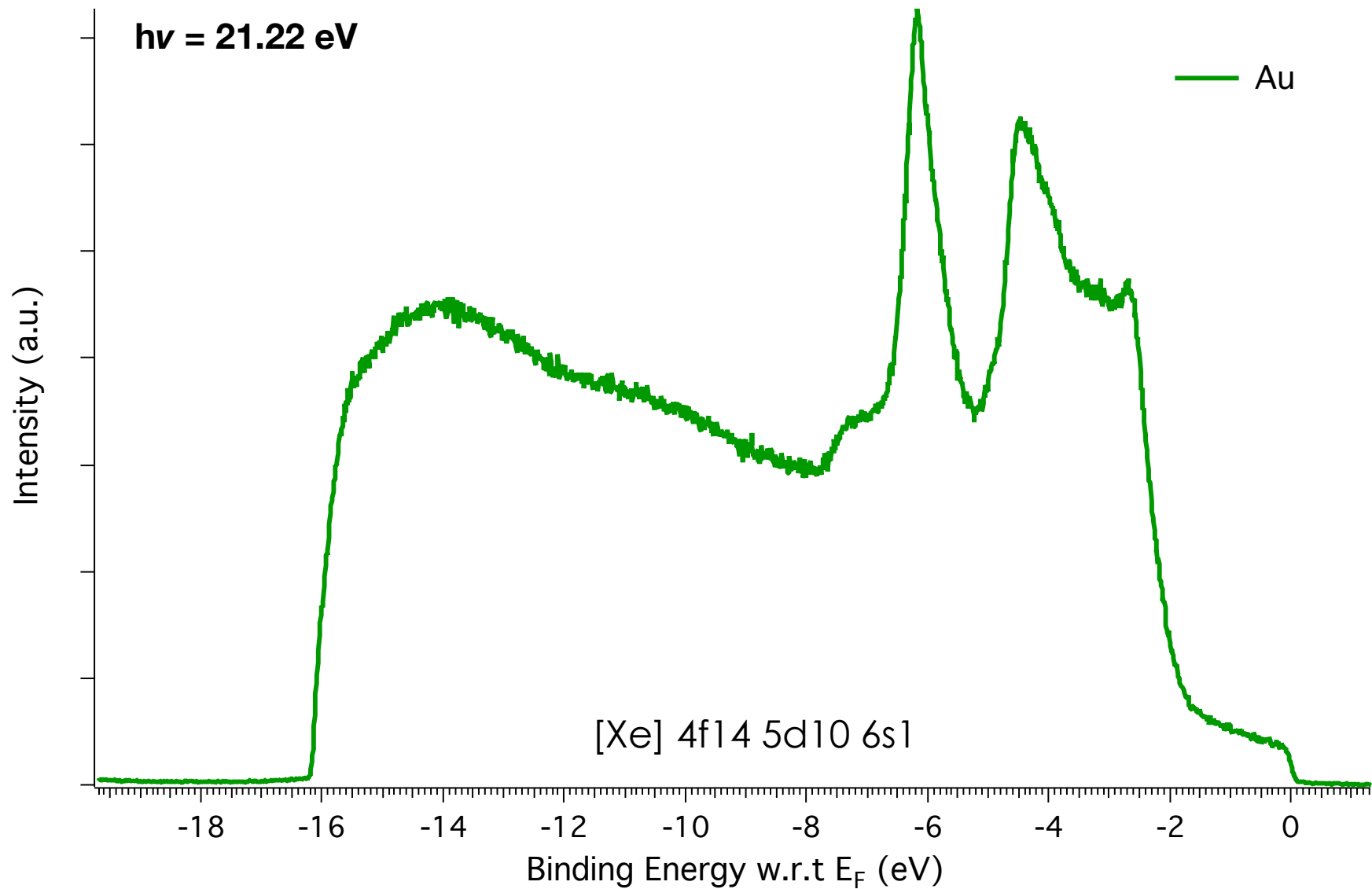
Fermi Level Reference

$$f(E) = \frac{1}{\exp\left[\frac{E - E_f}{kT}\right] + 1}$$

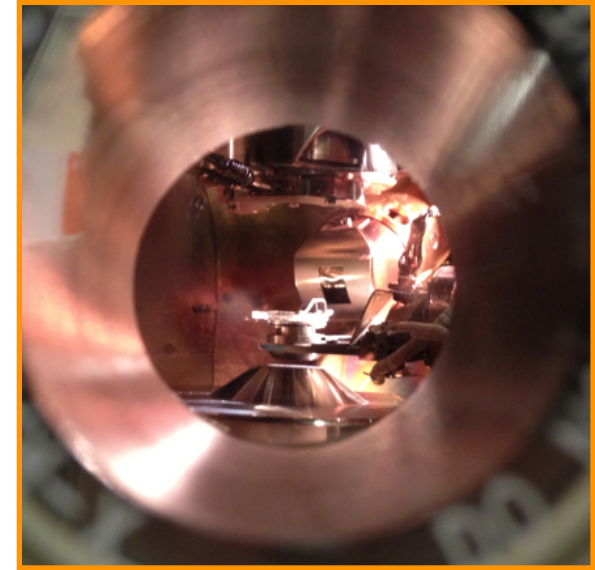
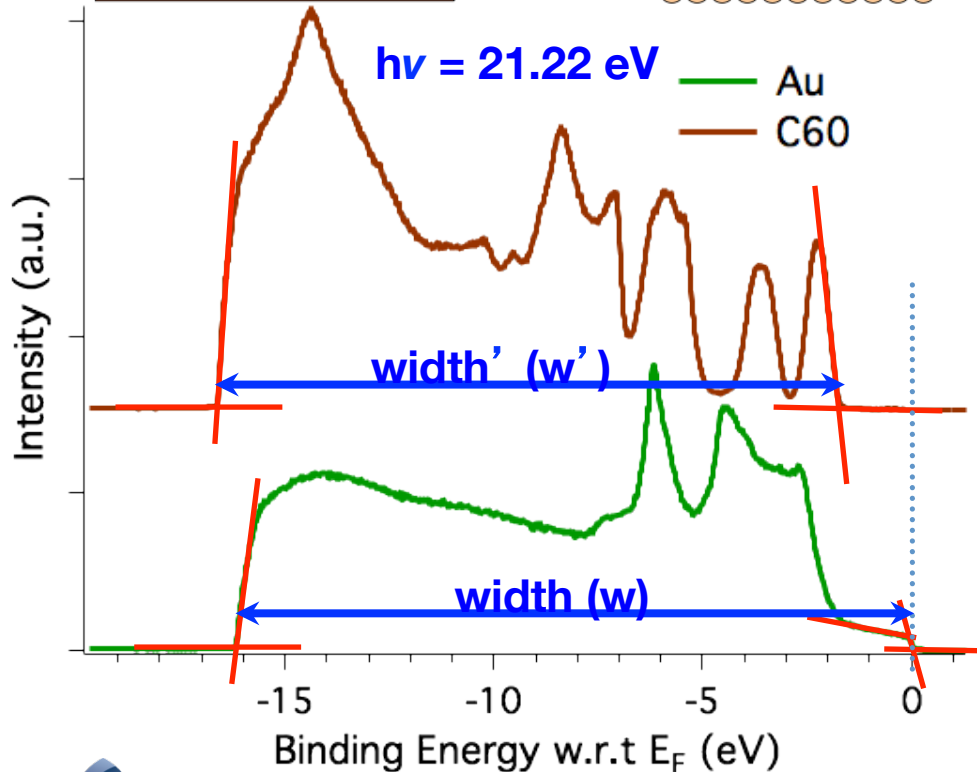
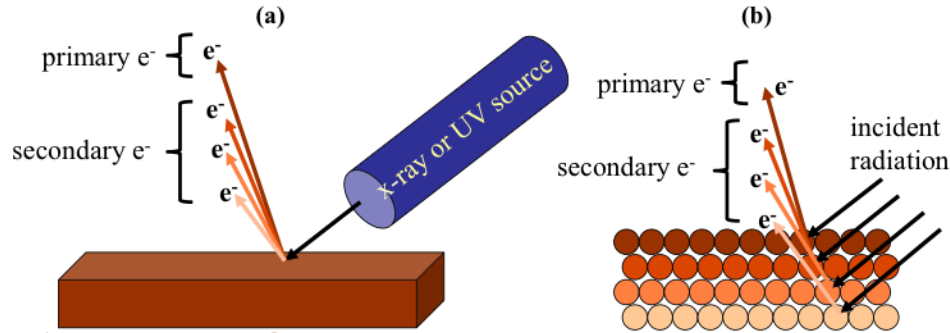


T = 0K **f(E)=1 for E < E_f**
f(E)=0 for E > E_f

kT << E_f **f(E)=0.5 for E = E_f**



Ultraviolet photoelectron spectroscopy



$$\phi = h\nu - (E_{\text{Fermi}} - KE_{\text{low}})$$

$$\text{IP} = h\nu - (KE_{\text{high}} - KE_{\text{low}})$$

Spectral Analysis

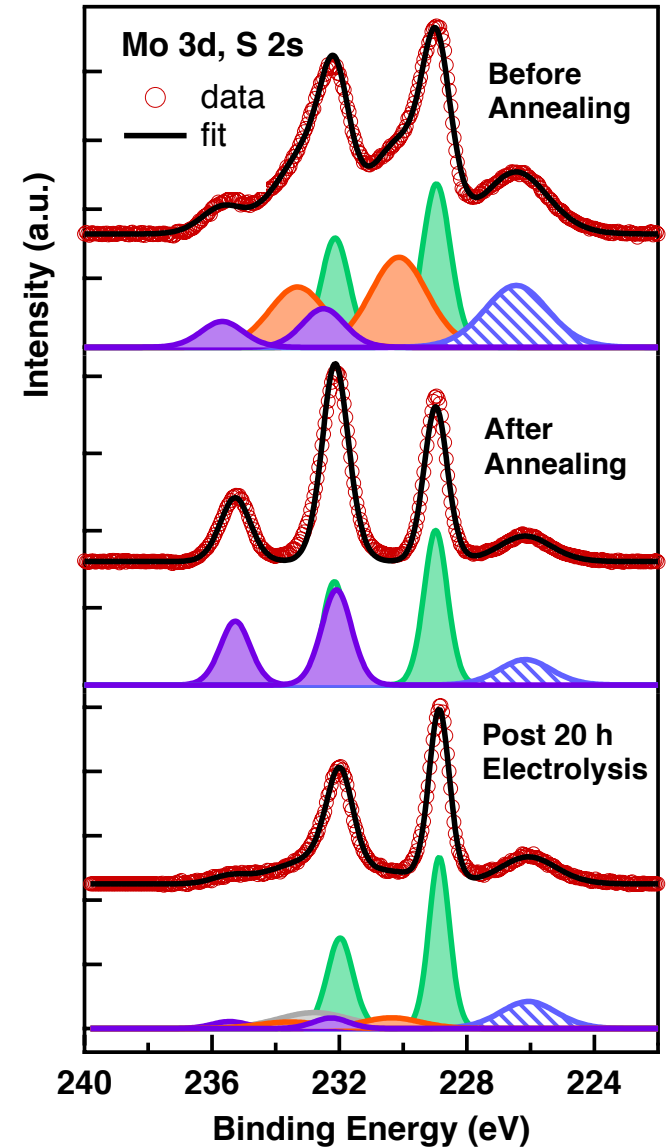
- Sample charging
- Auger transitions
- Plasmon loss
- X-ray satellites
- X-ray “ghosts”
- Overlapping peaks
- Spectral ID
- Chemical shifts

$$l = \begin{matrix} 0...s \\ 1...p \\ 2...d \\ 3...f \end{matrix}$$

$$n \rightarrow 3d_{5/2}$$

$$j = l - s$$

$$j = l + s$$



Gu, Aguiar, Ferrere, Steirer, Yan, Xiao, Young, Al-Jassim, Neale, Turner, *Nature Energy*, 2016 accepted

ksteirer@mines.edu

PES as a Research Tool

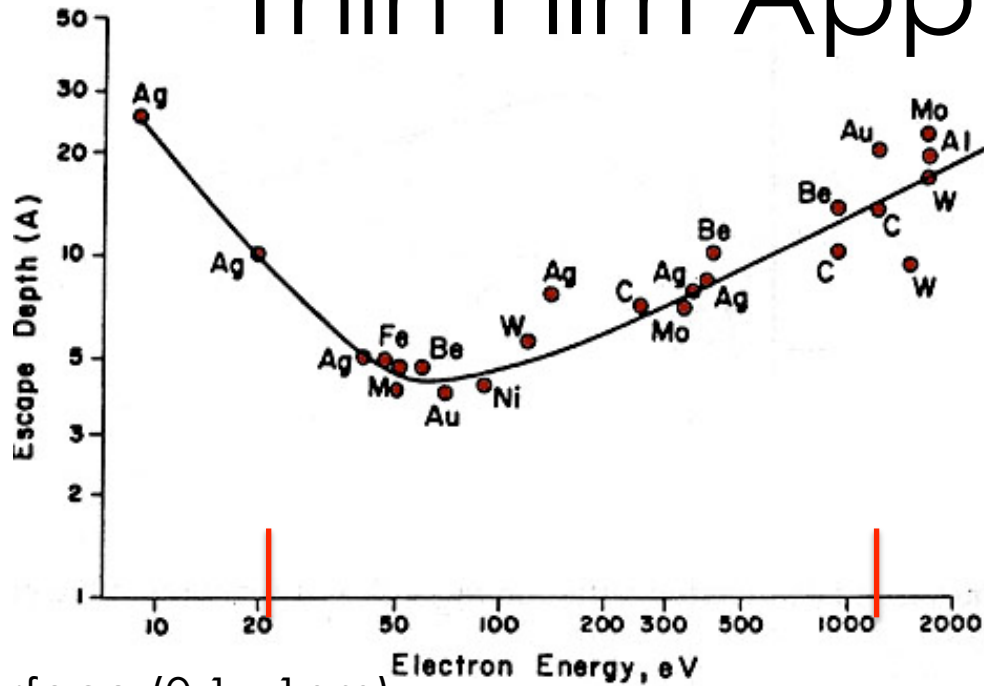
- Limitations

- Requires high vacuum \$\$
- Slow data acquisition/processing
- Large Area Required
- H and He not Measureable
 - Only Li and up

- Advantages

- Non-destructive
- Surface Sensitive
~few nm
- Quantitative Composition
- Identifies Chemical States
- Measures Electronic Structures of Surfaces and Interfaces

Thin Film Applications



Surface (0.1 - 1nm)

Ultra-thin film (up to 10 nm)

Thin Film (10nm - 1µm)

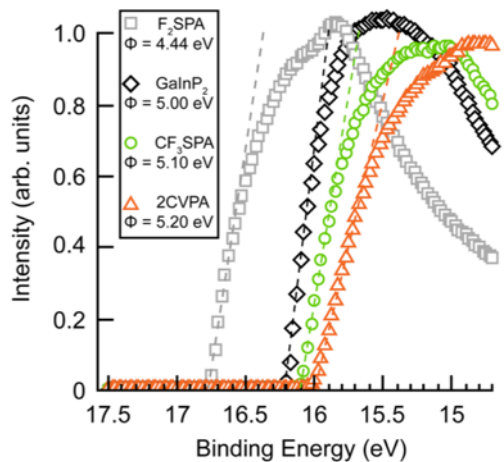
Bulk Material

- Surfaces:
 - Wetting
 - Soldering
 - Catalysts
 - Work Function
 - Optics
 - Diffusion
- Ultra-Thin Films
 - Contacts
 - Oxidation
 - Passivation
 - Tribology
 - Gate Dielectrics
 - Optics
 - Diffusion

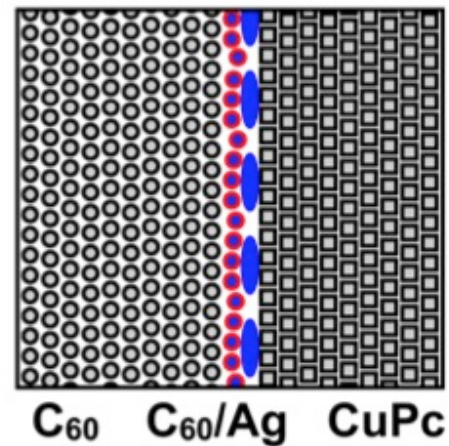
- <http://xpssimplified.com/whatisxps.php>
- http://www.virginia.edu/ep/SurfaceScience/electron_interactions.htm

PES Research Topics

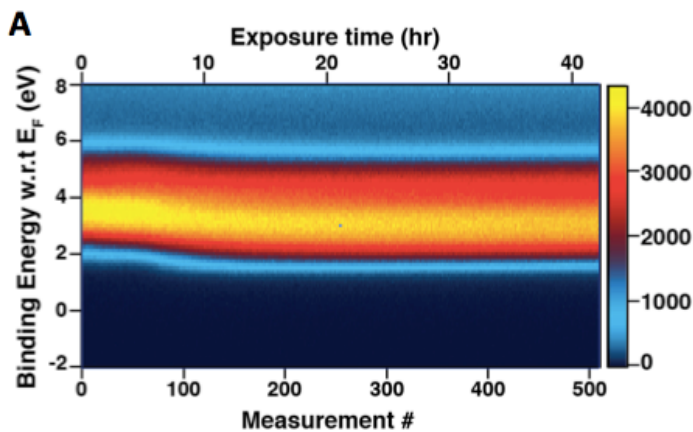
Dipole Studies



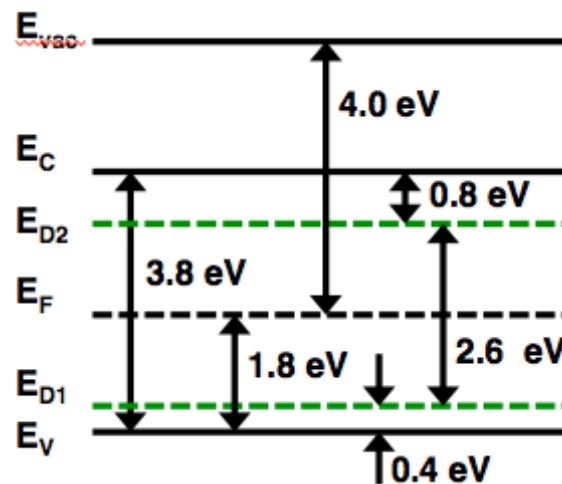
Nanostructured Interfaces



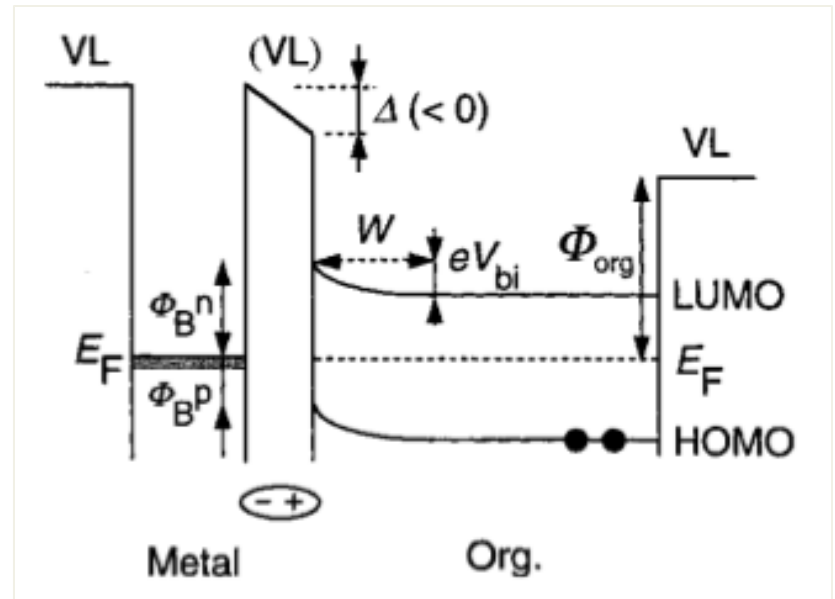
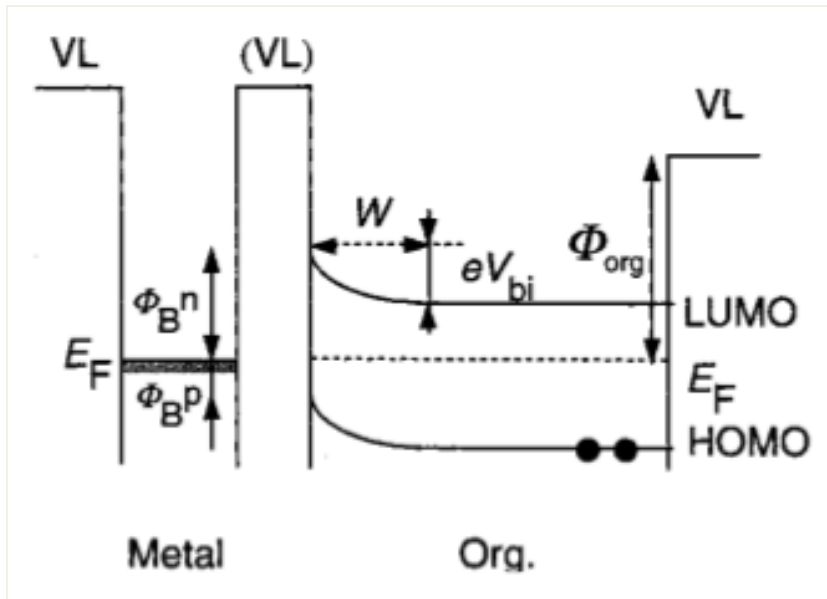
Phase Transformations



Defect Assessments

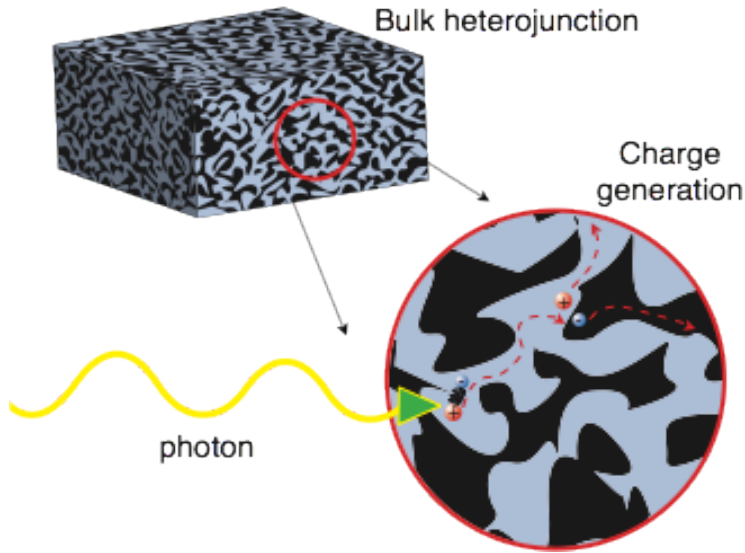


Interface dipole effects



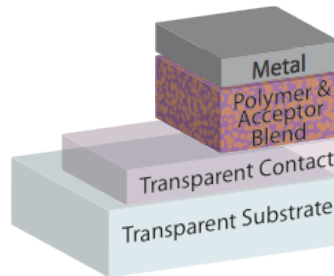
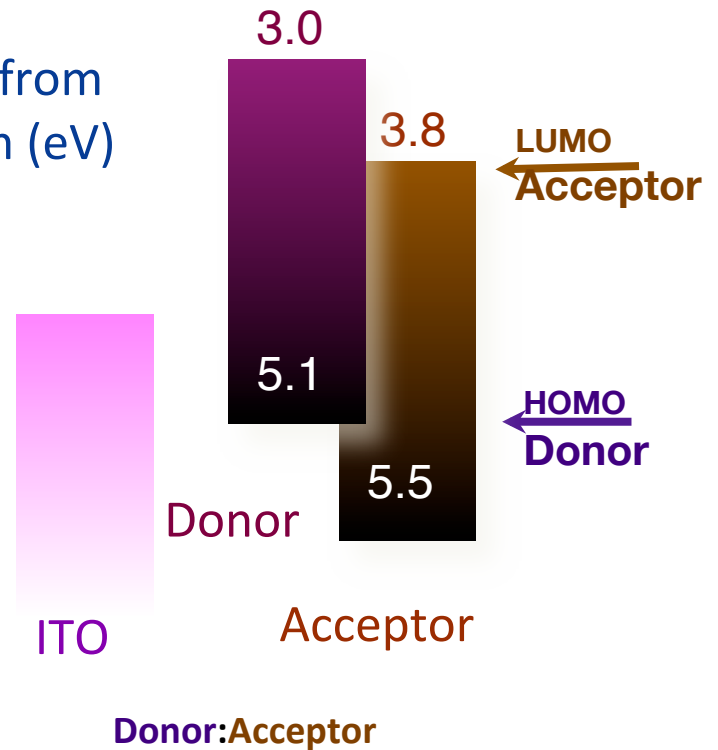
Ishii, H., Sugiyama, K., Ito, E. & Seki, K. *Adv. Mater.* **11**, 605–625 (1999).

Bulk Heterojunction PV



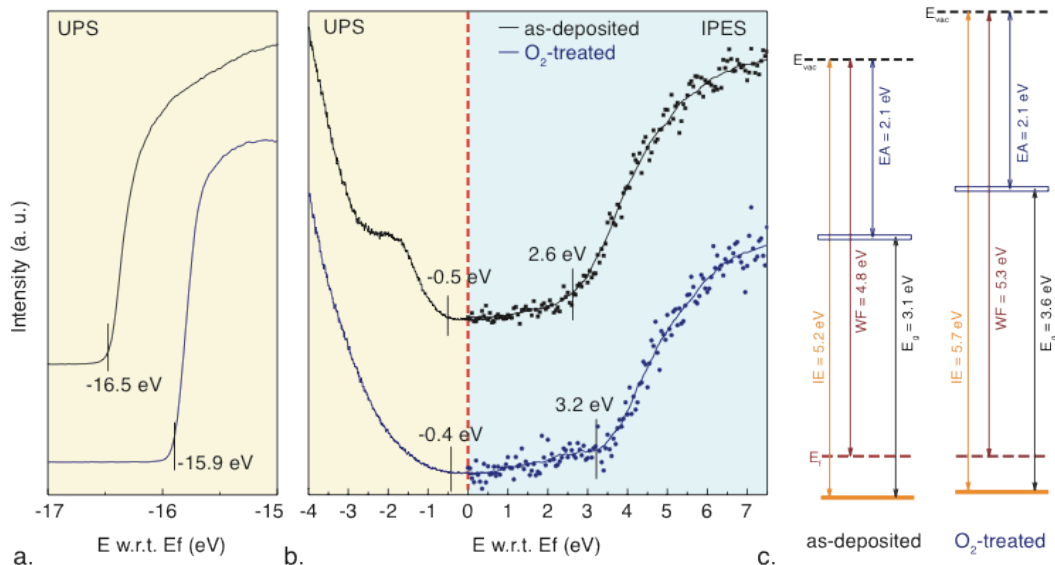
$$V_{OC} \leq \frac{1}{q} |LUMO_A - HOMO_D| - 0.3V$$

Energy from Vacuum (eV)

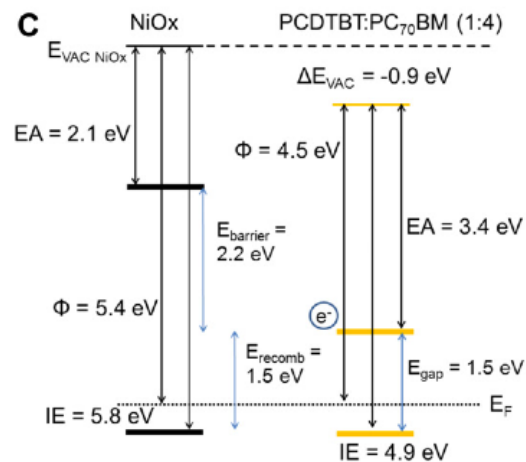


- Hole contact affects:
 - Photovoltage
 - Photocurrent
 - Diode behavior

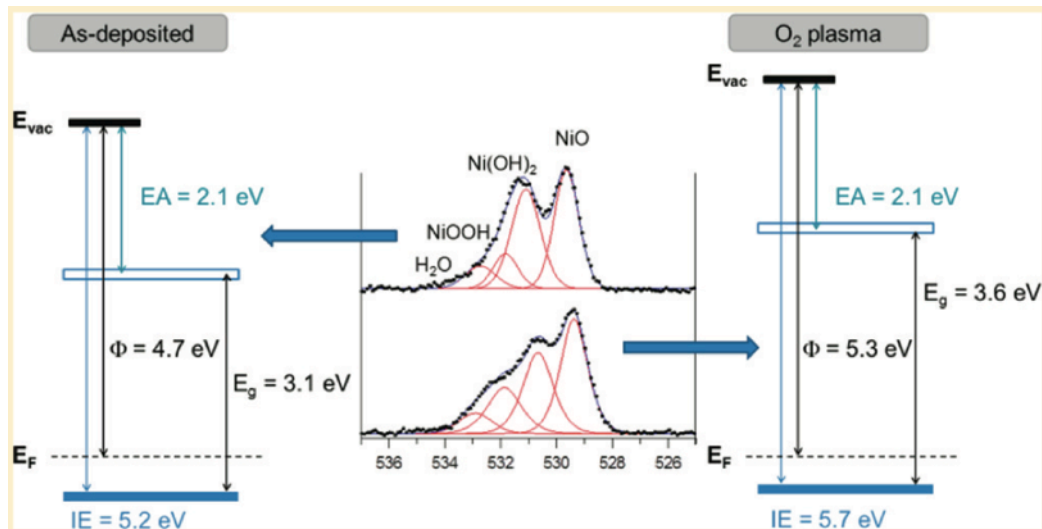
NiOOH Structure-Property-Function



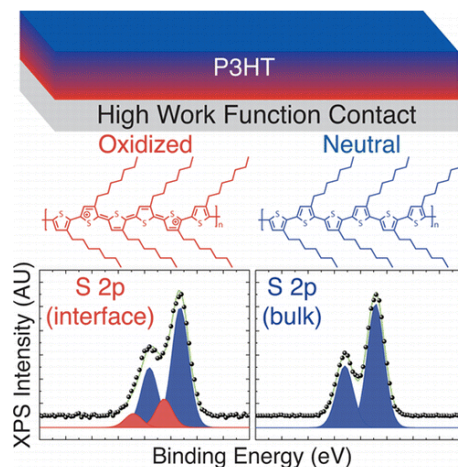
Steirer, Ndione, Widjonarko, Lloyd, Meyer, Ratcliff, Kahn, Armstrong, Curtis, Ginley, Berry, Olson, *Adv. Energy Mater.* **1** 813, (2011)



Ratcliff, Meyer, Steirer, Armstrong, Olson, Kahn, *Organic Electronics*, **13** 744, (2012)

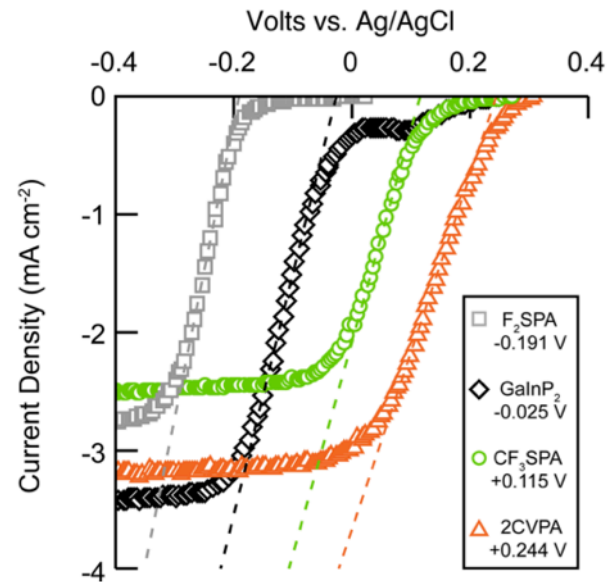
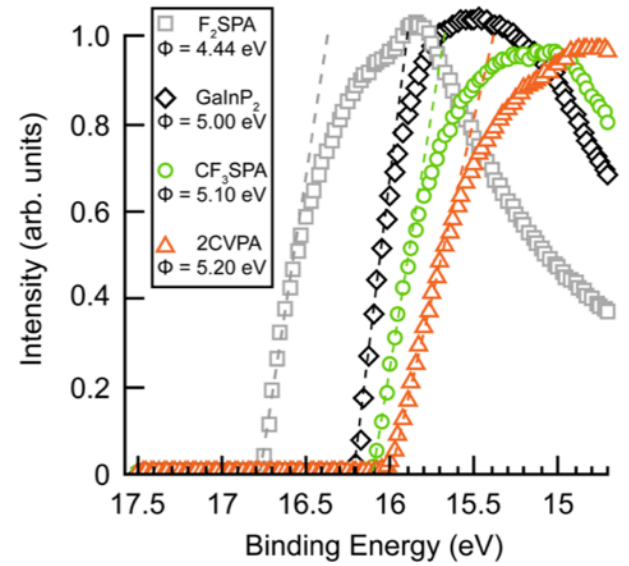
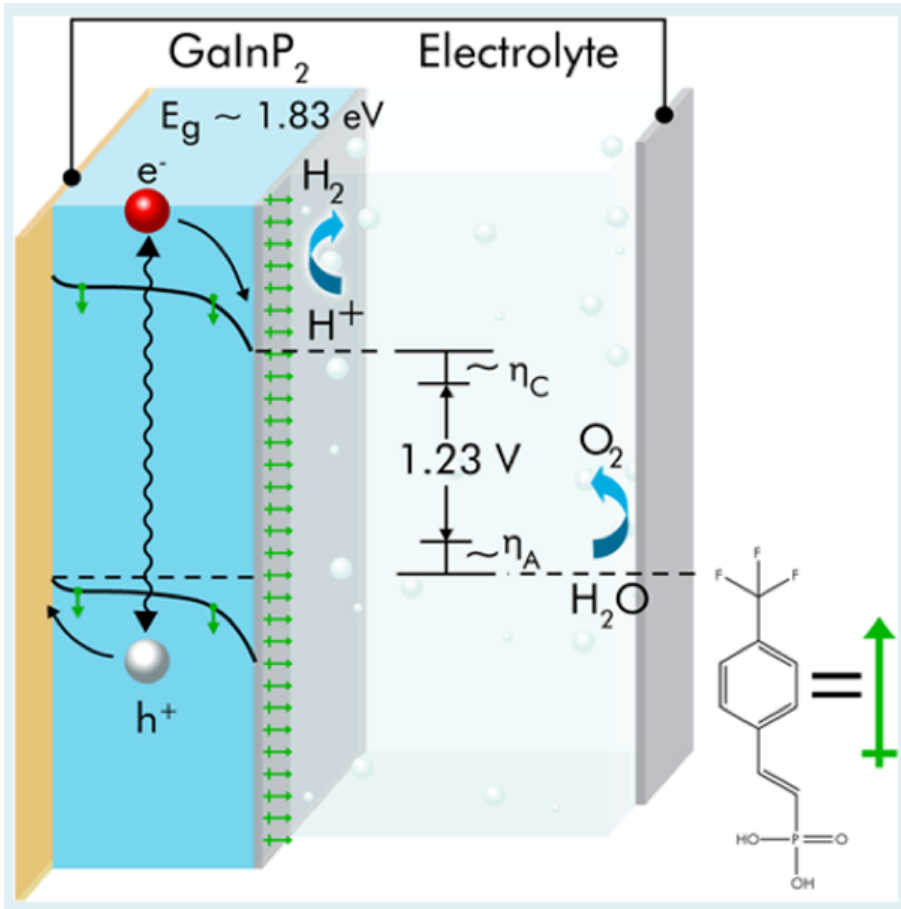


Ratcliff, Meyer, Steirer, Garcia, Berry, Ginley, Olson, Kahn, Armstrong *Chemistry of Materials* **23**, 4988 (2011)



C. Shallcross, et al., *J. Phys. Chem. Lett.*, **6** 1303, (2015)
ksteirer@mines.edu

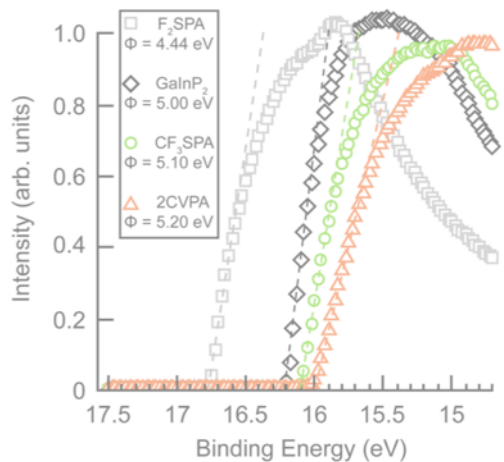
Dipole effect in photoelectrochemistry



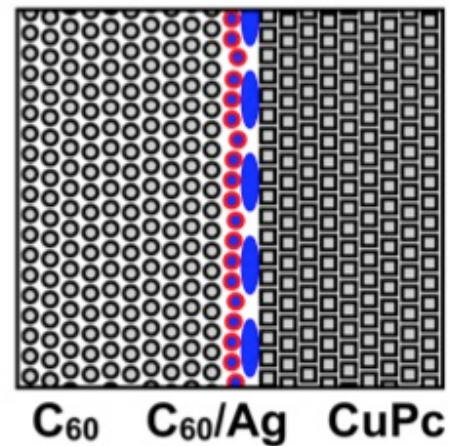
MacLeod, Steirer, Young, Koldemir, Sellinger, Turner, Deutsch, Olson, ACS Appl. Mater. Interfaces 7, 11346–11350 (2015).

PES Research Topics

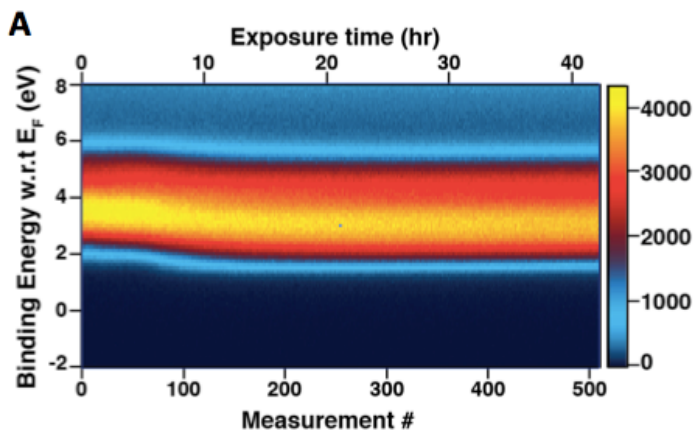
Dipole Studies



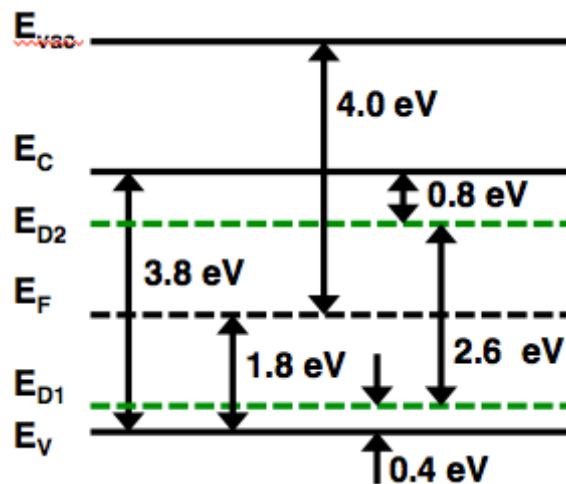
Nanostructured Interfaces



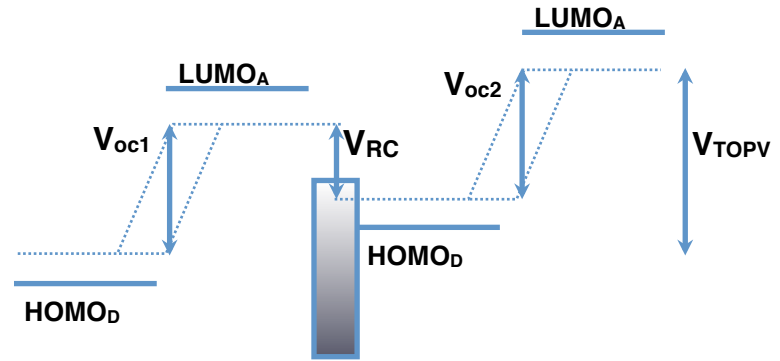
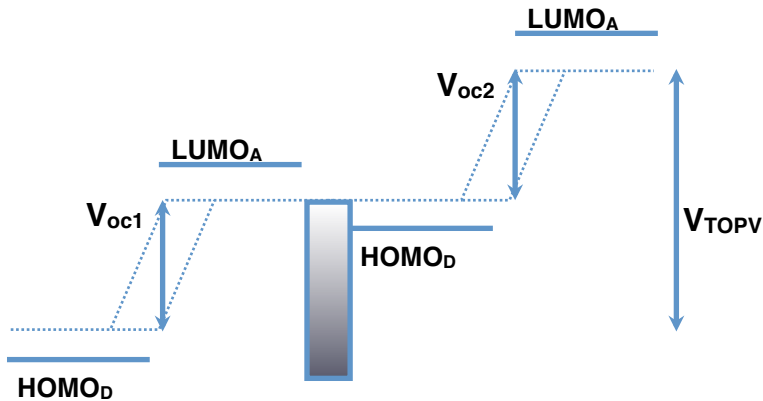
Phase Transformations



Defect Assessments

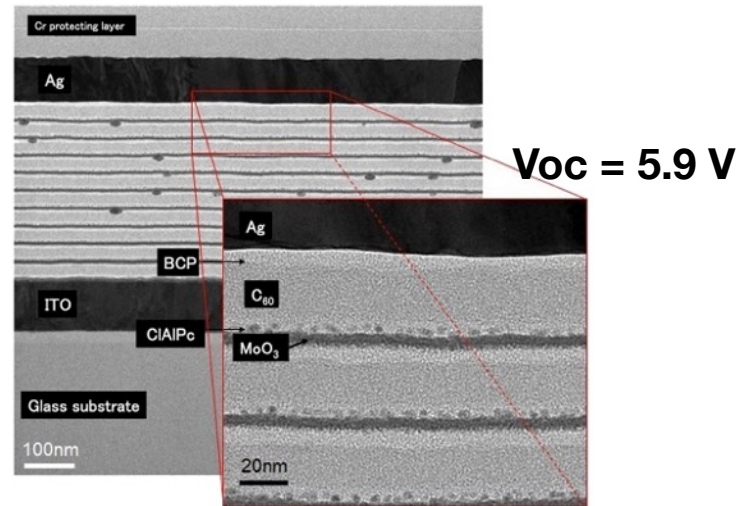
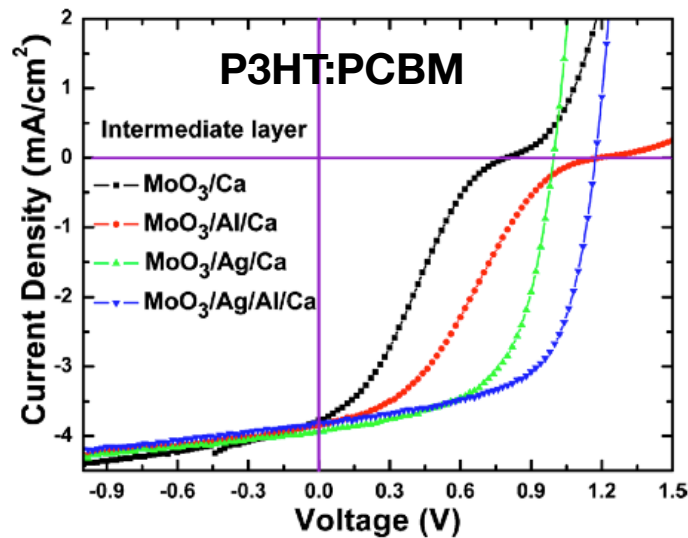


Voltage loss at recombination interface



Donor/Acceptor Metal Donor/Acceptor

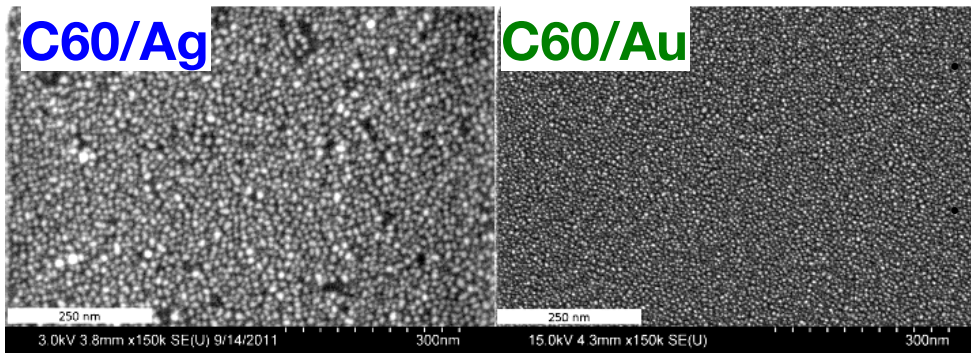
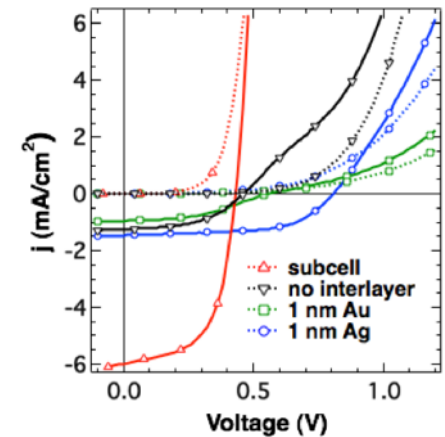
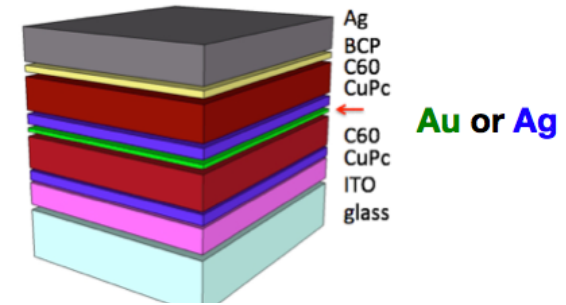
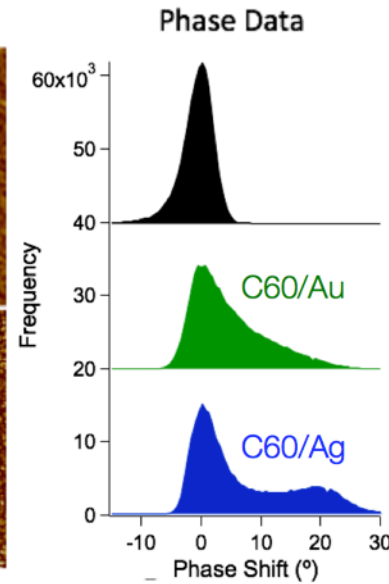
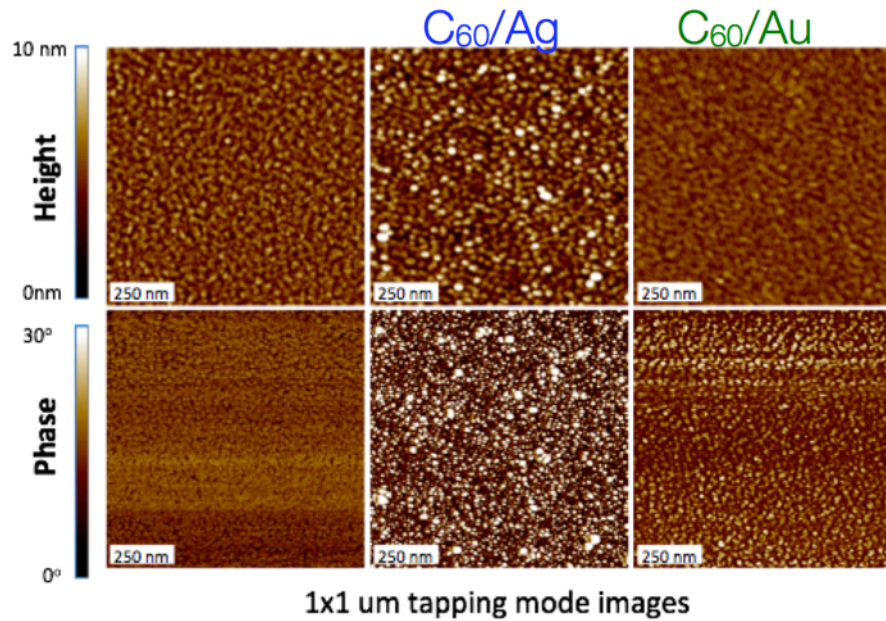
Donor/Acceptor Metal Donor/Acceptor



Sun et al. *Applied Physics Letters* (2010) vol. 97 (5) pp. 053303

Zou et al. *Applied Physics Letters* (2012) vol. 100 (24) pp. 243302

Morphology of Metal/Fullerene

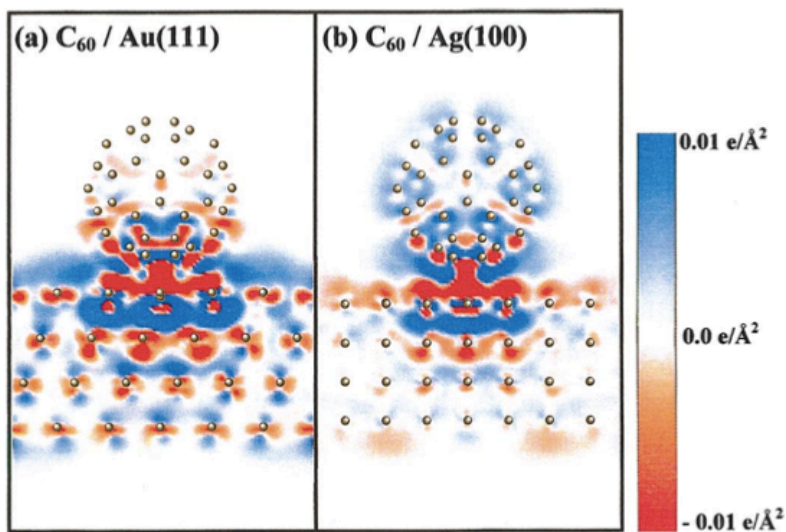
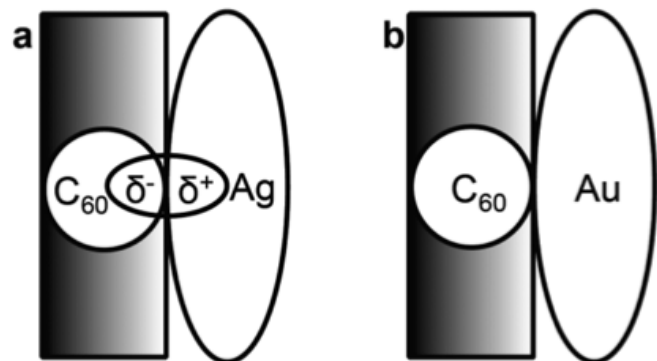


Diameters: Ag (15 nm)
larger than Au (7 nm)

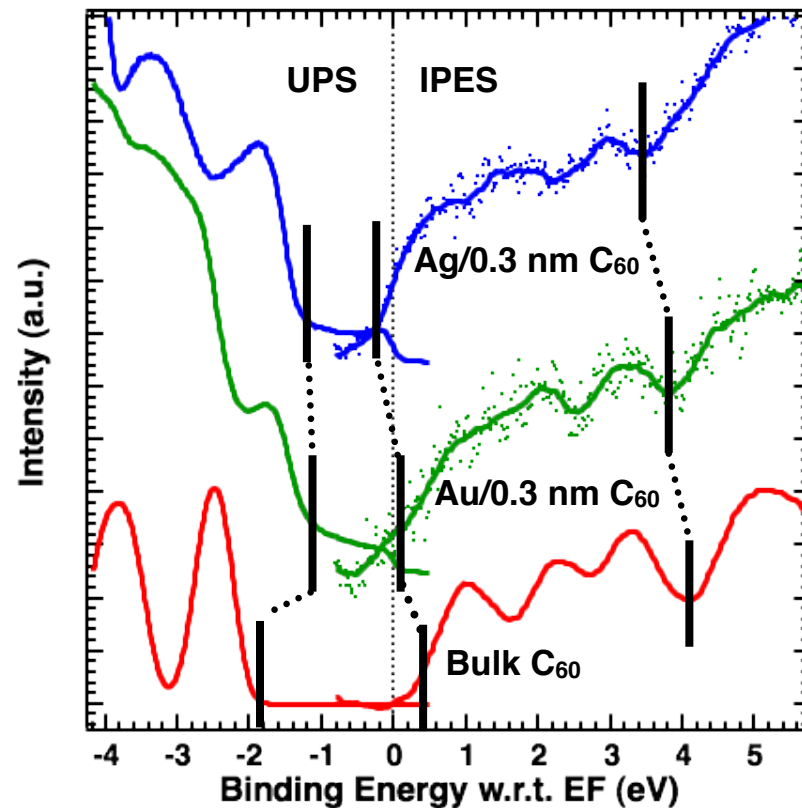
Au over-layer is more
uniformly dispersed

Device	V_{oc} (V)
subcell	0.43
No-interlayer	0.45
1 nm Au	0.56
1 nm Ag	0.81

Polarized interfaces

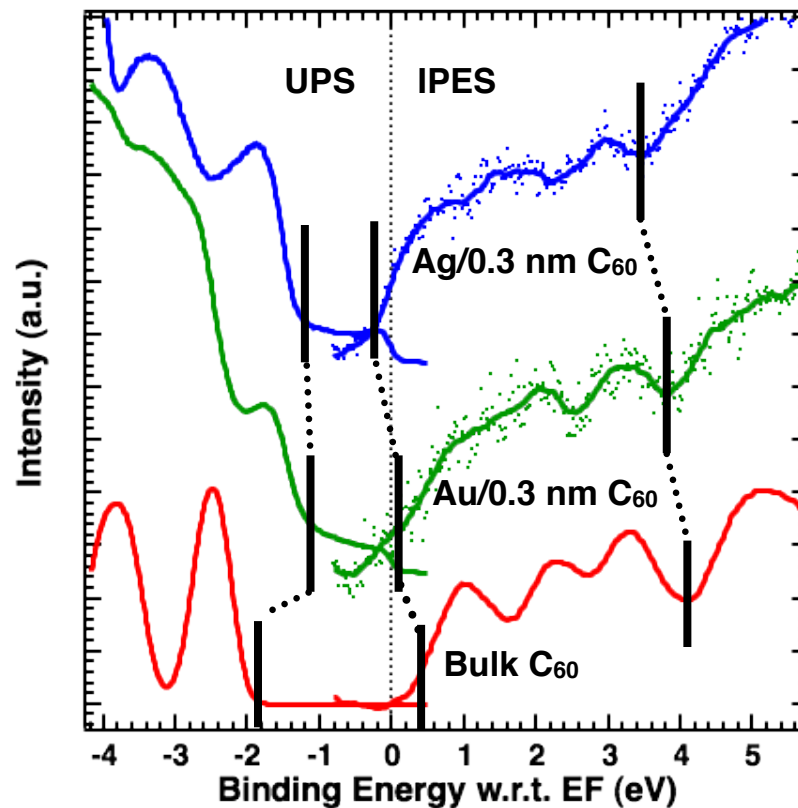
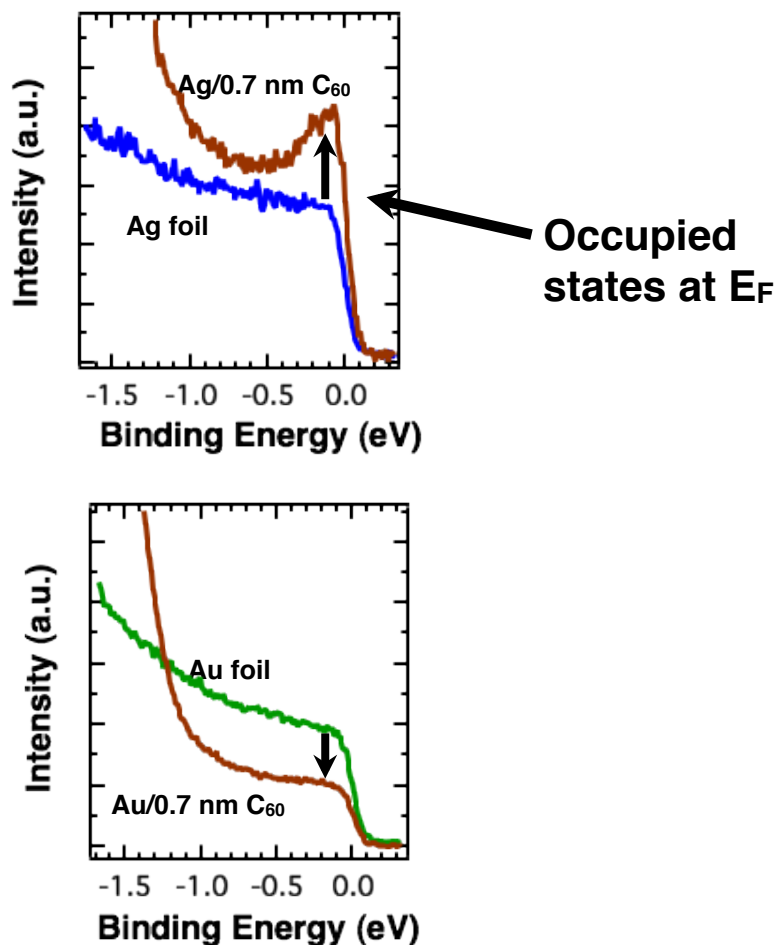


Lu, X., Grobis, M., Khoo, K., Louie, S. & Crommie, M.
Phys. Rev. B **70**, 115418 (2004).



K Steirer, G MacDonald, S Olthof, J Gantz, E Ratcliff, A Kahn, and N Armstrong, *J Phys Chem C* 117(2013)p22331.

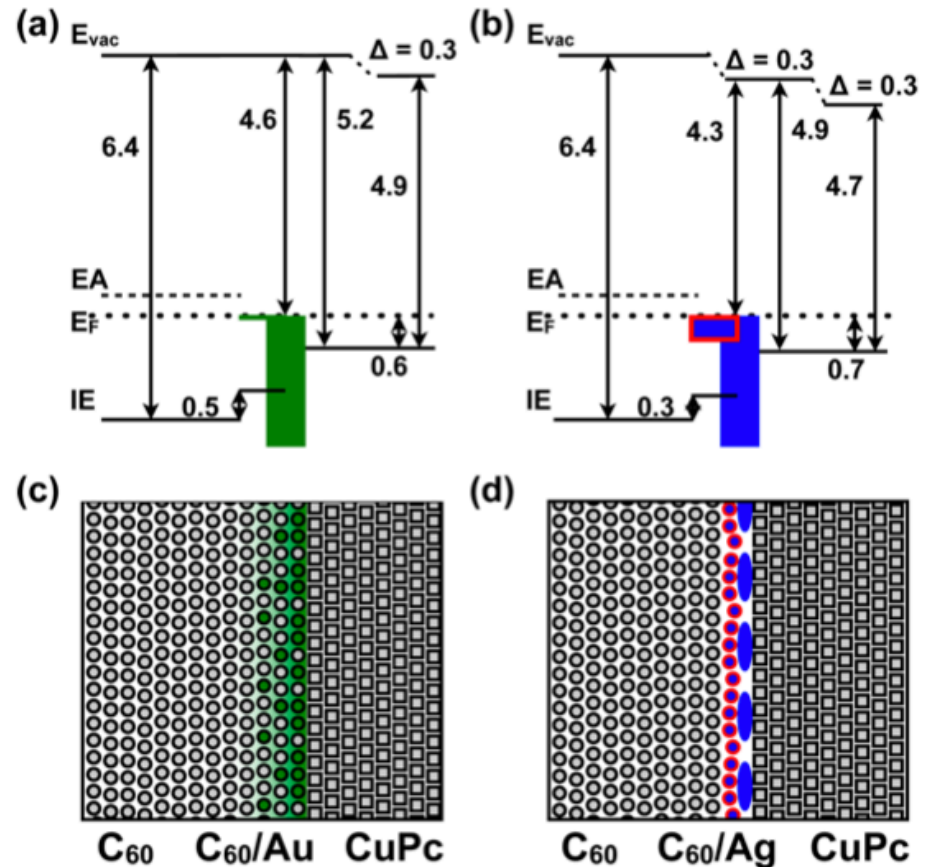
Charge redistribution at C₆₀/Metal



K Steirer, G MacDonald, S Olthof, J Gantz, E Ratcliff, A Kahn, and N Armstrong, *J Phys Chem C* 117(2013)p22331.

Combined morphology and energetics

Device	V_{oc} (V)
<u>subcell</u>	0.43
No-interlayer	0.45
1 nm Au	0.56
1 nm Ag	0.81

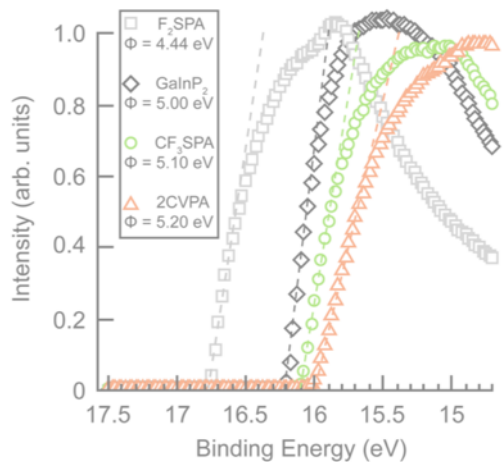


- Reduced electronic gap for C₆₀ due to
 - mirror potential
 - rehybridized frontier molecular orbitals
 - delocalized interface state with Ag
- NPs form at both interlayers
 - affected by the nucleation and growth
 - Au is more uniform but less effective
- Voc addition may be result of **exohedral doping/charge redistribution**

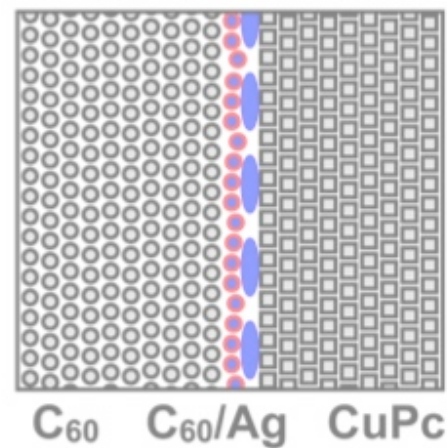
K Steirer, G MacDonald, S Olthof, J Gantz, E Ratcliff, A Kahn, and N Armstrong, *J Phys Chem C* 117(2013)p22331.

PES Research Topics

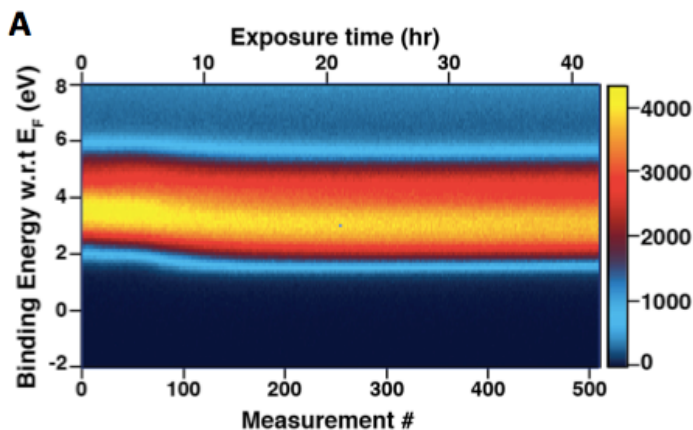
Dipole Studies



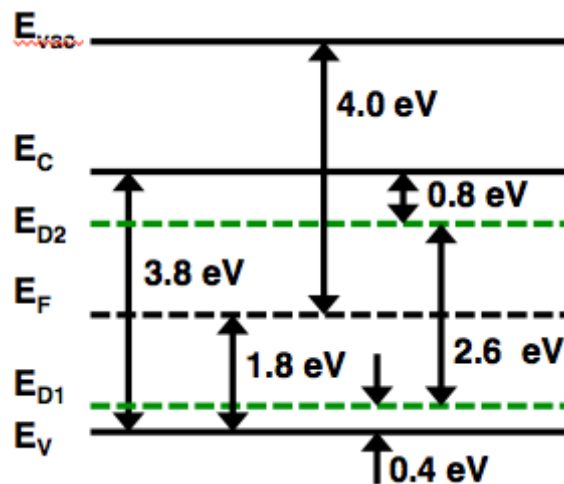
Nanostructured Interfaces



Phase Transformations

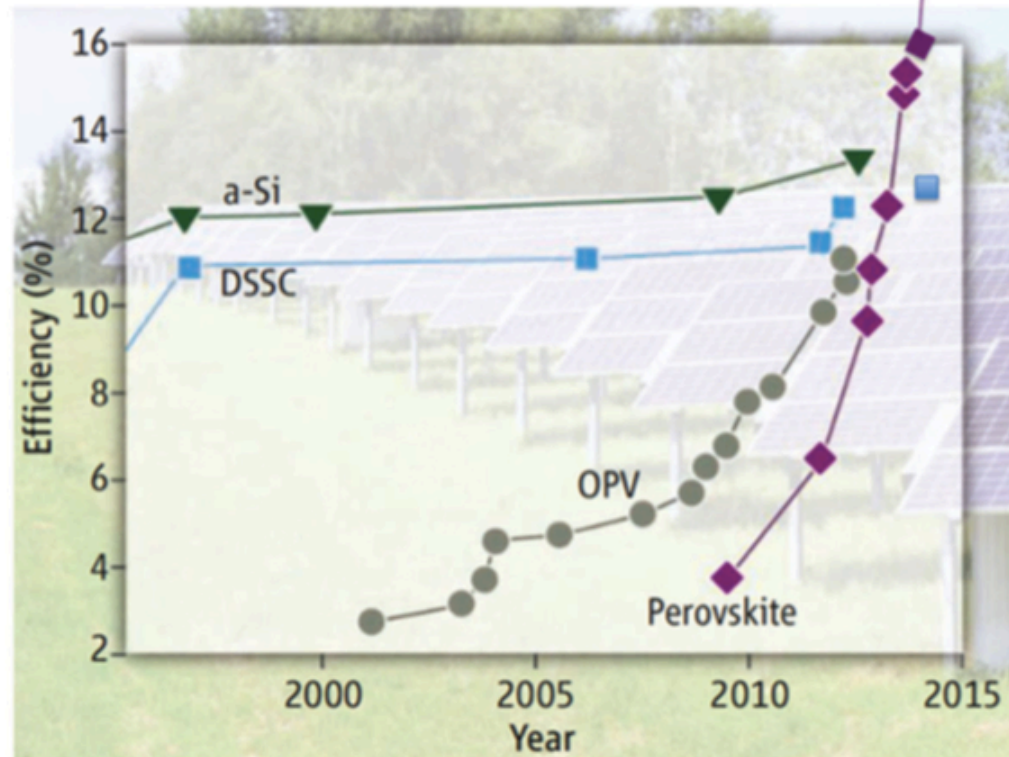


Defect Assessments



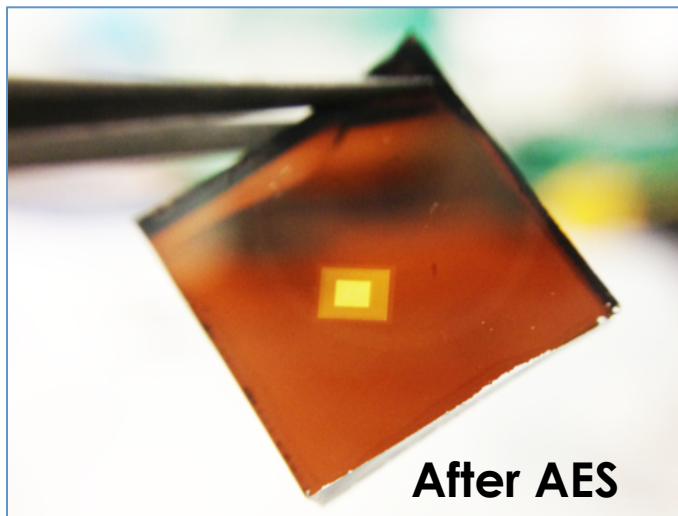
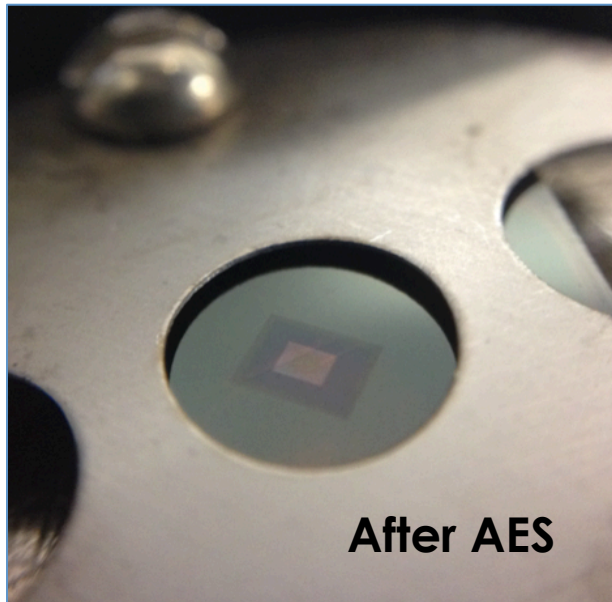
Unprecedented Progress

Evolution of hybrid I-O Perovskite solar cells



Berry, J., Buonassisi, T., et al. Hybrid Organic-Inorganic Perovskites (HOIPs): Opportunities and Challenges. *Adv. Mater.* **27**, 5102–5112 (2015).

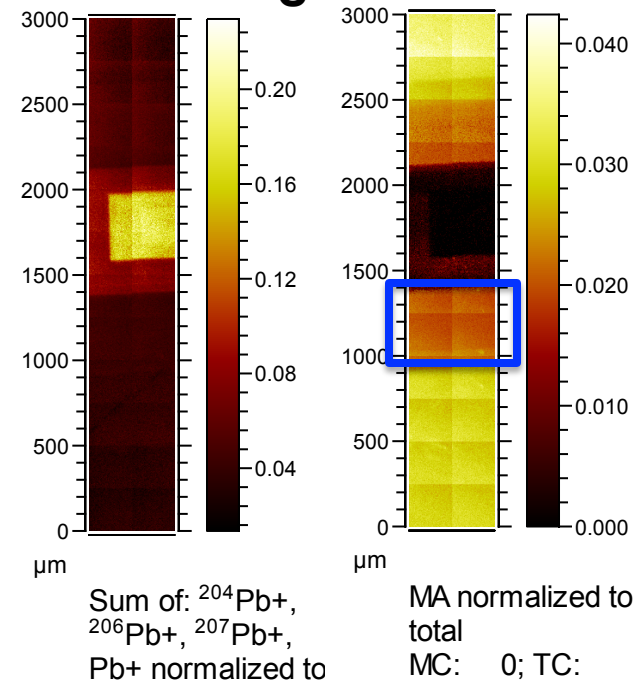
Electron Degraded $\text{CH}_3\text{NH}_3\text{PbI}_3$



SIMS: 3mm x 0.5mm 2-D surface map
e- damage

Edge of
damaged
perovskite

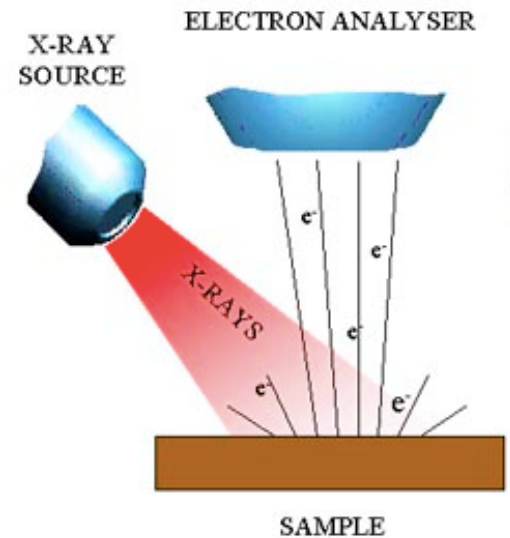
Undamaged
perovskite



- Important for [XPS](#), UPS, and e-beam techniques such as IPES, AES, SEM, EBIC, etc.

Approach

- X-ray flux $\sim 1.5 \times 10^{11}$ ph/cm²s
 - Can vary by tilting sample, anode choice, changing spectrometers
 - 2 mm Al mono
 - 45° incident
 - Minimum spot
 - 5.4×10^{14} ph/cm²hr
- Measure (x510 over 42 hr)
 - elemental %
 - chemical state (BE)
 - valence spectra (E_V)
- Choose vacuum stable MAPI samples (2×10^{-10} torr)
 - Glass/FTO/TiO₂/MAPI
 - Stable in vacuum up to one week



$$I = N \sigma D J L \lambda A T$$

$$N = \text{atoms/cm}^3$$

$$\sigma = \text{photoelectric cross-section, cm}^3$$

$$D = \text{detector efficiency}$$

$$J = \text{X-ray flux, photon/cm}^2 \text{ sec}$$

$$L = \text{orbital symmetry factor}$$

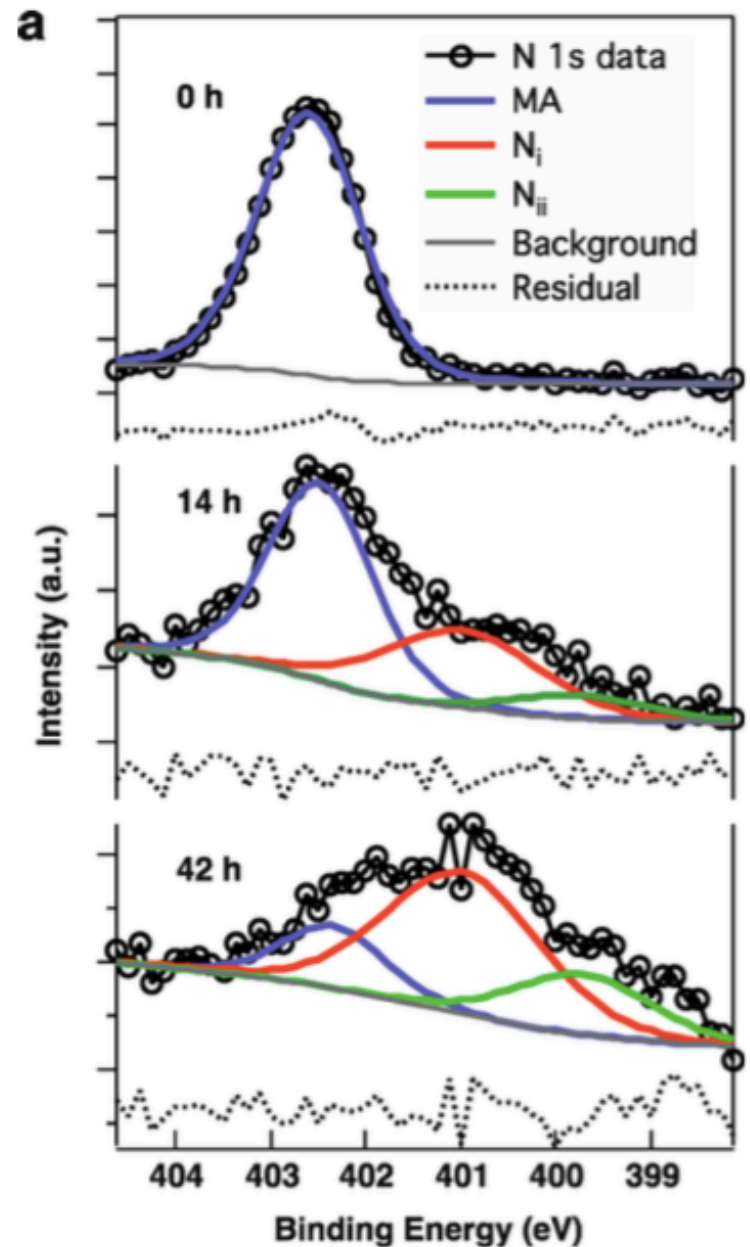
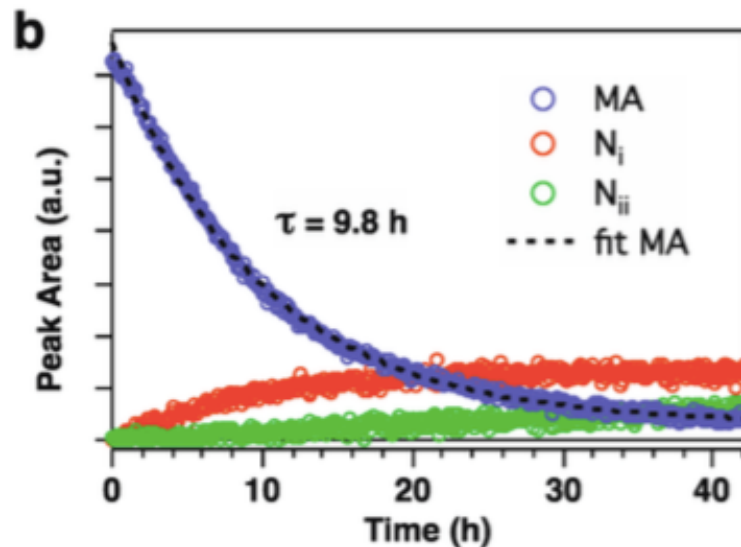
$$\lambda = \text{inelastic electron mean-free path, cm}$$

$$A = \text{analysis area, cm}^2$$

$$T = \text{analyzer transmission efficiency}$$

Loss of CH_3NH_3

- N 1s intensity decay follows 1st order kinetics
- Degradation products also observed



• Steirer, K. X., Schulz, P., et al., *ACS Energy Lett.* **1**, 360–366 (2016).

Uniformly Changing Composition

- Uniform CH_3NH_3 profile
- Slight I surface enrichment
- For $n = 3$, 3D growth
- For $n = 1$, constant nucleation rate

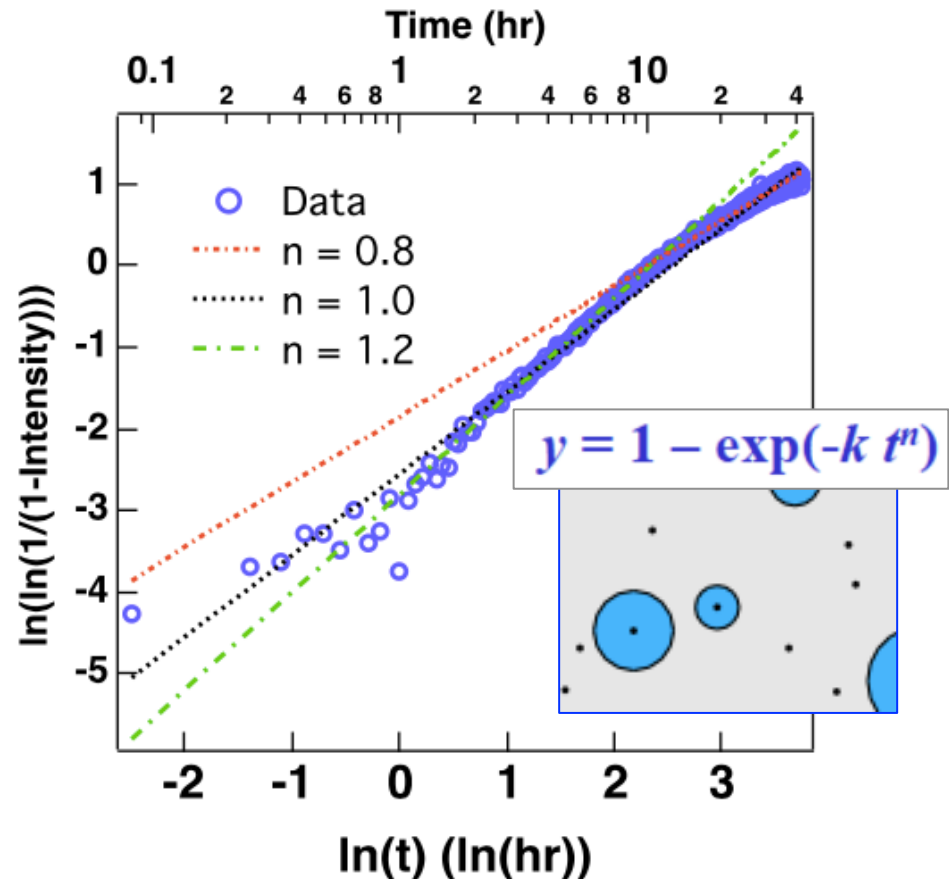
ARXPS Atomic Concentration

N 1s **I 3d_{5/2}** **Pb 4f_{7/2}** (RSF Factor)

(0.499) (6.302) (5.172)

16.9 59.4 23.7 **60° Take Off**

16.7 57.0 26.3 **6° Take Off**

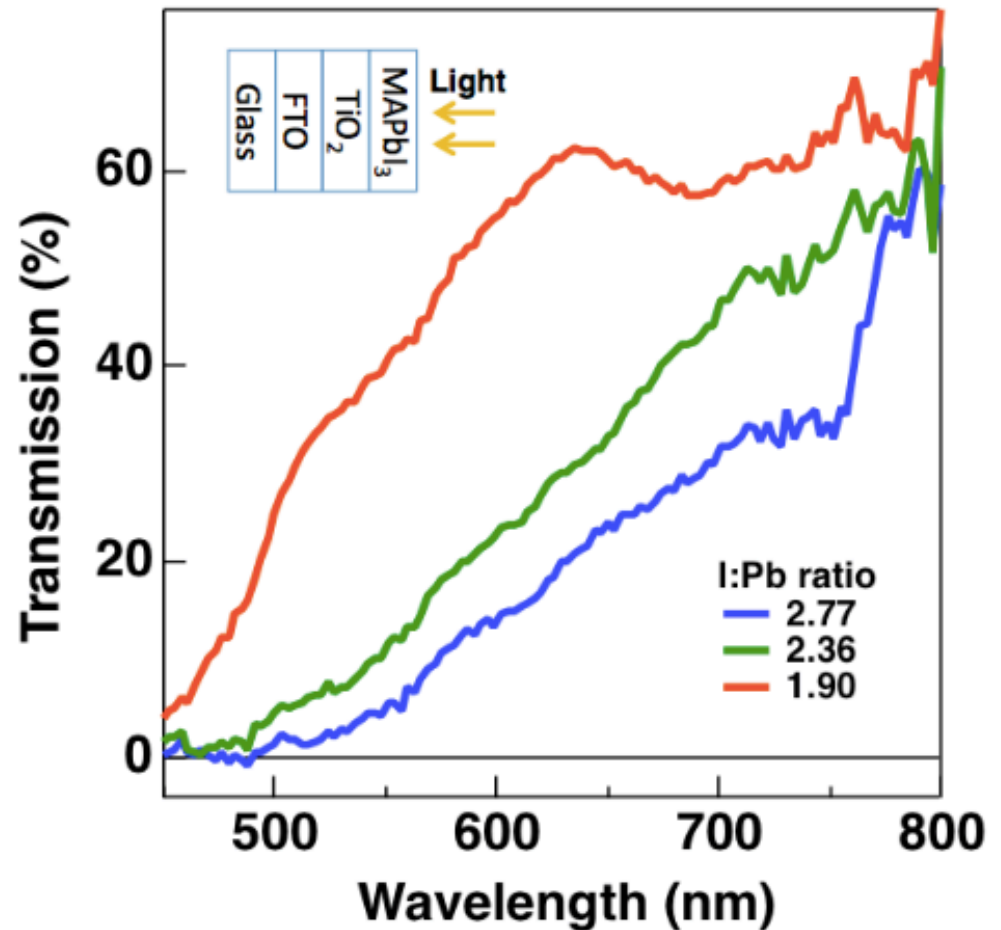


Avrami, M., Granulation, Phase Change, and Microstructure Kinetics of Phase Change. III, *Journal of Chemical Physics*, 9, 177 (1941)

Du, Z. H., et al., Perovskite crystallization kinetics and dielectric properties of the PMN-PT films ..., *J. Mater. Res.* **24**, 1576–1584 (2009).

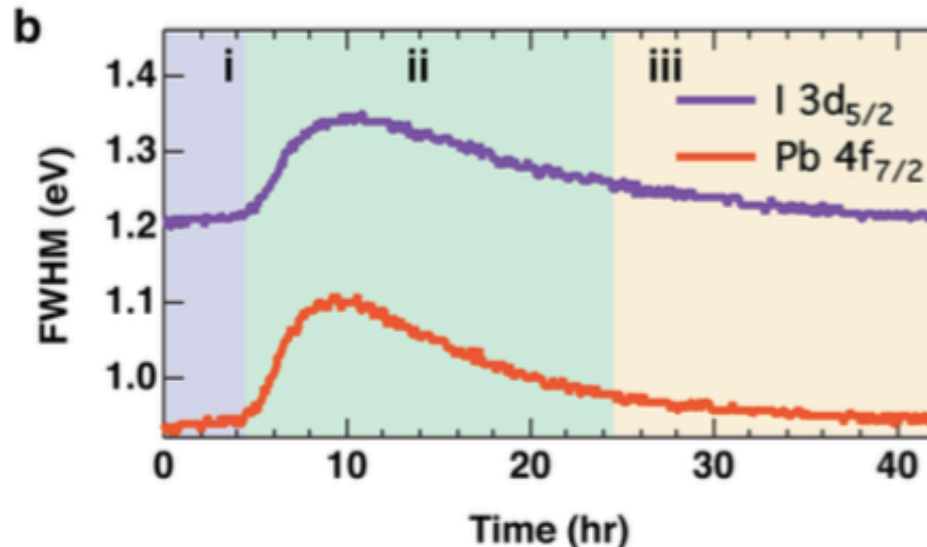
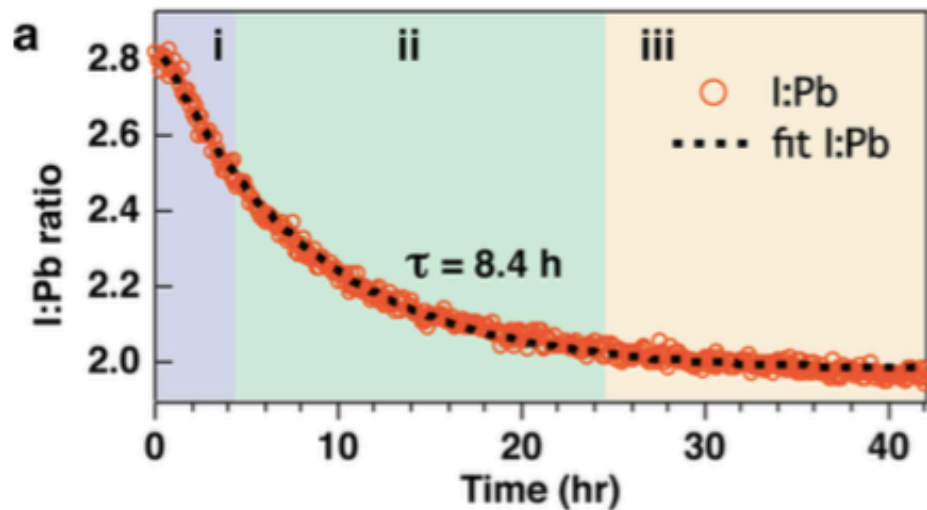
Bulk Transformation to PbI_2

- E_g increases from 1.6 eV to 2.3 eV
- Entire film color changes to yellow



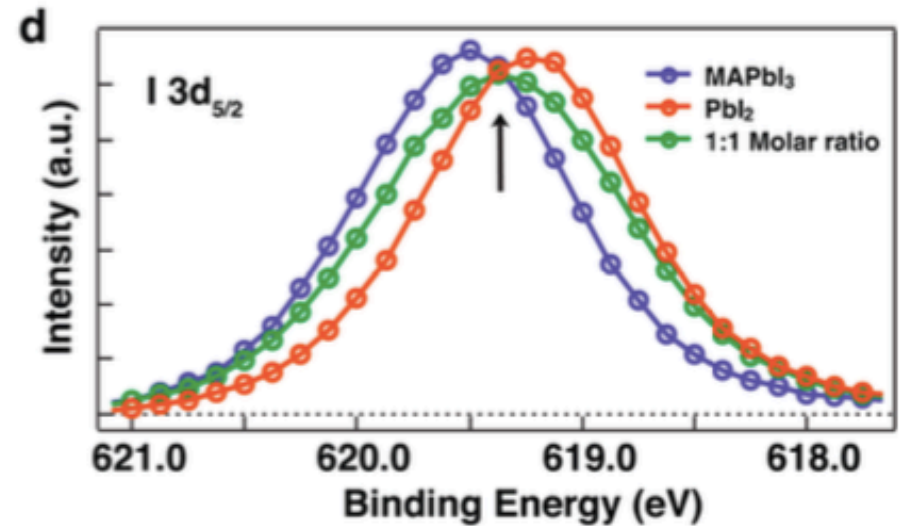
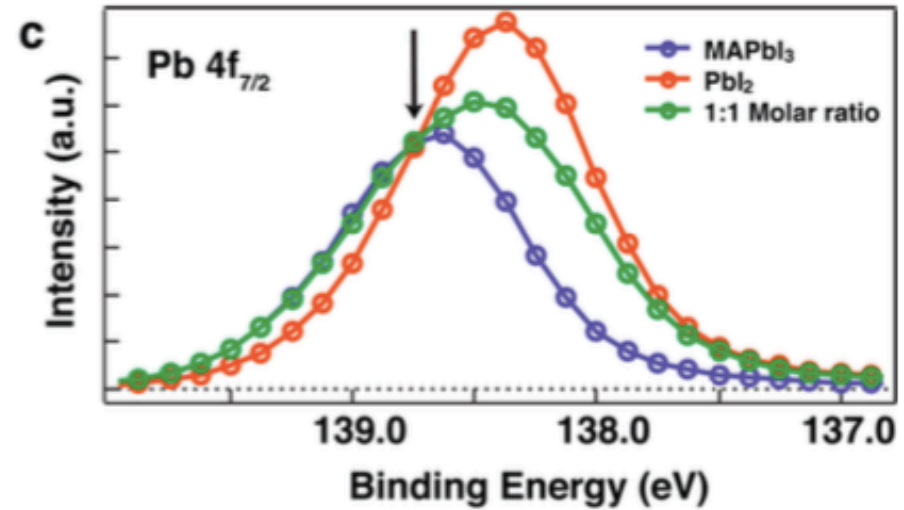
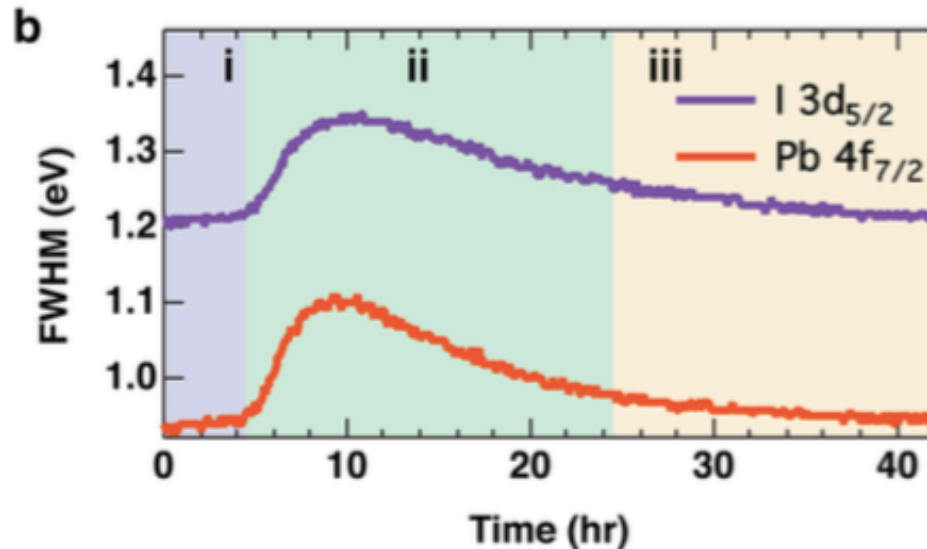
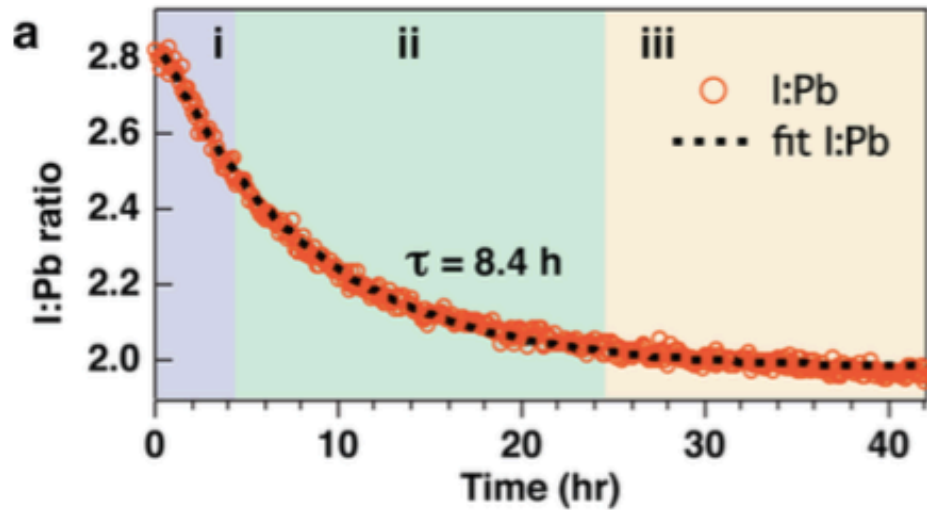
- Steirer, K. X., Schulz, P., et al., *ACS Energy Lett.* **1**, 360–366 (2016).

Delayed Chemical Transformation

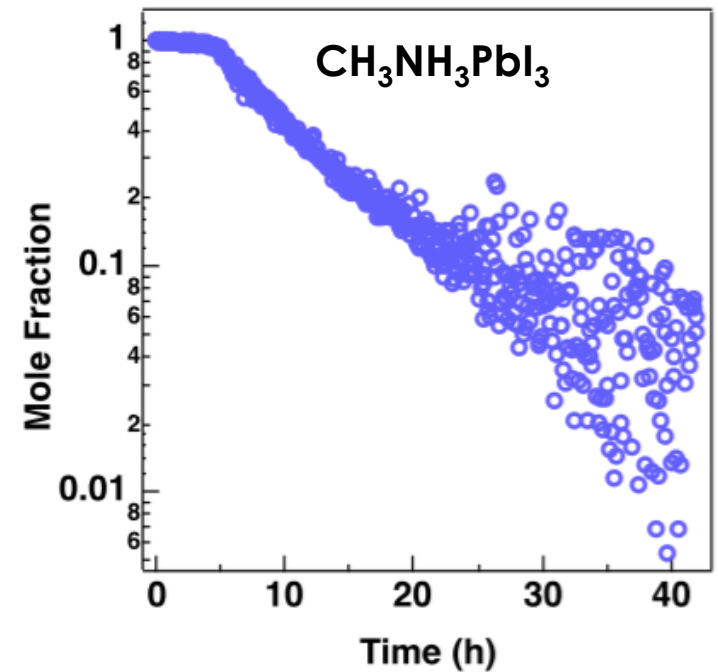
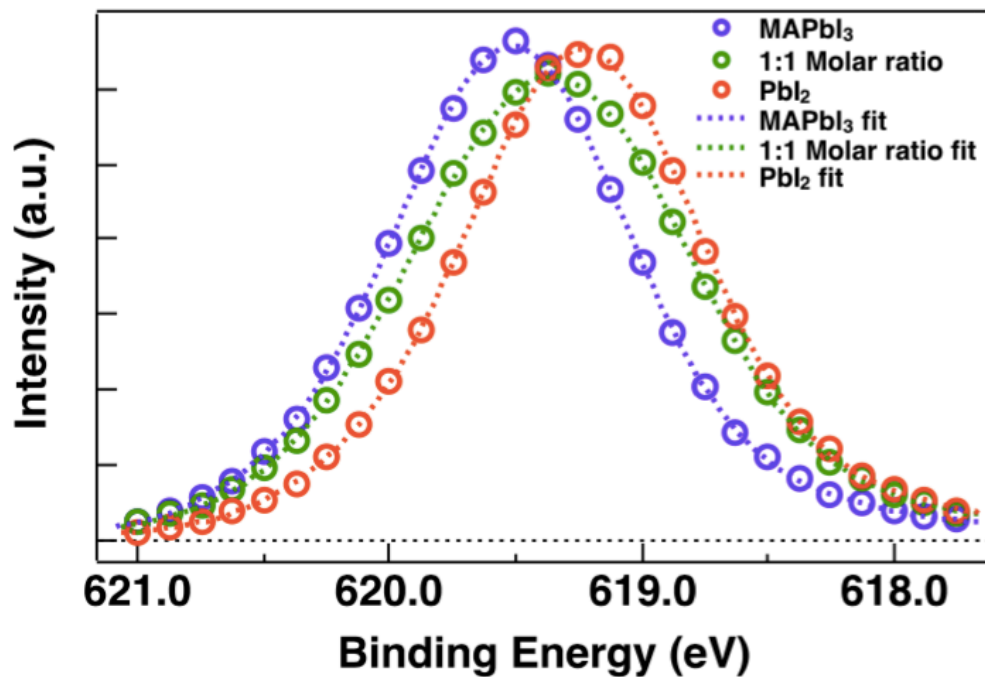


- I/Pb ratio decreases similarly to the N 1s intensity
- No chemical shift or increase FWHM for first 4.5 hr
- FWHM increases then decreases after 9.1 hr
- FWHM returns to original value upon long exposure

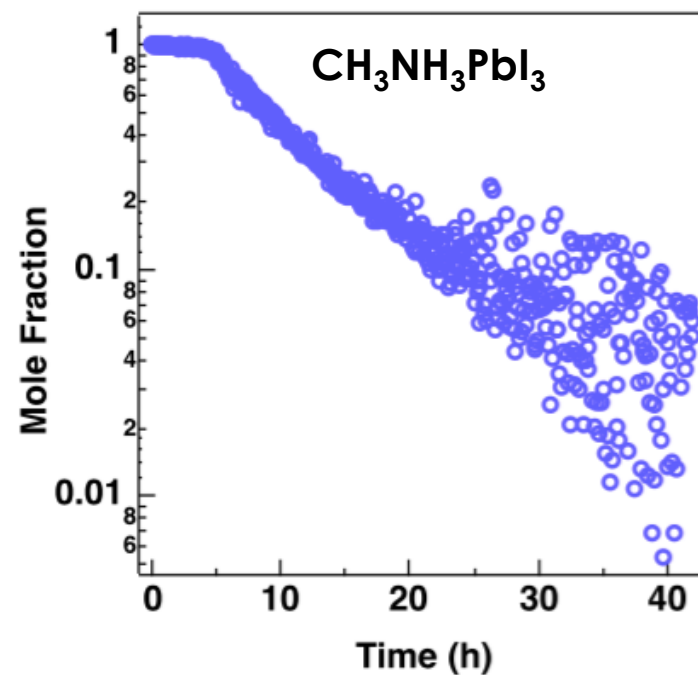
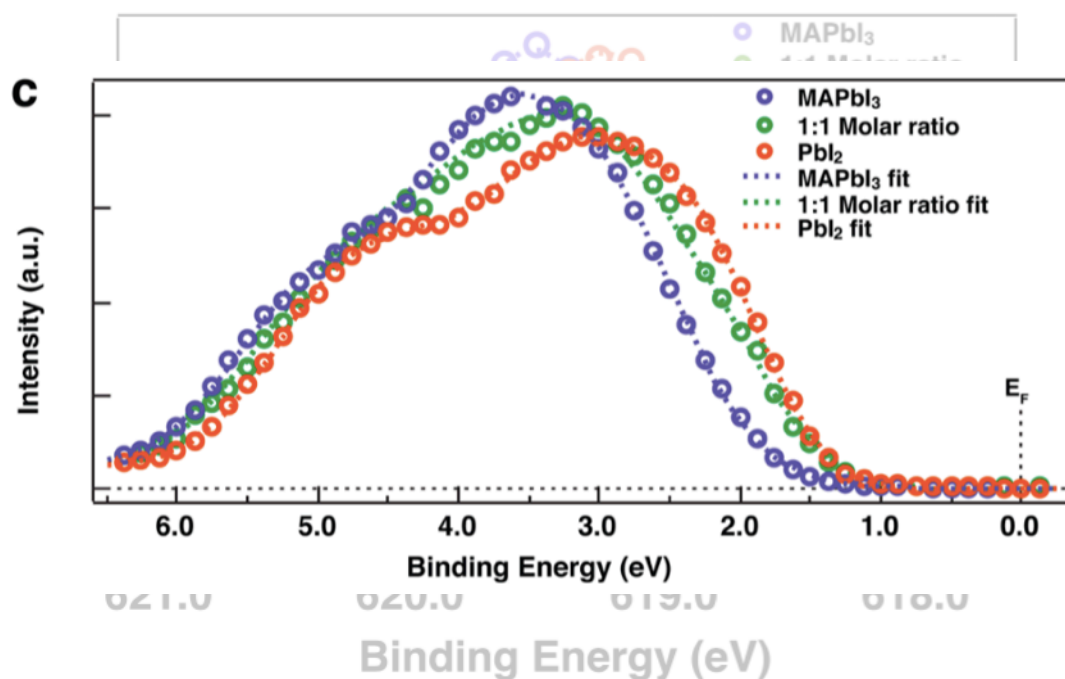
Delayed Chemical Transformation



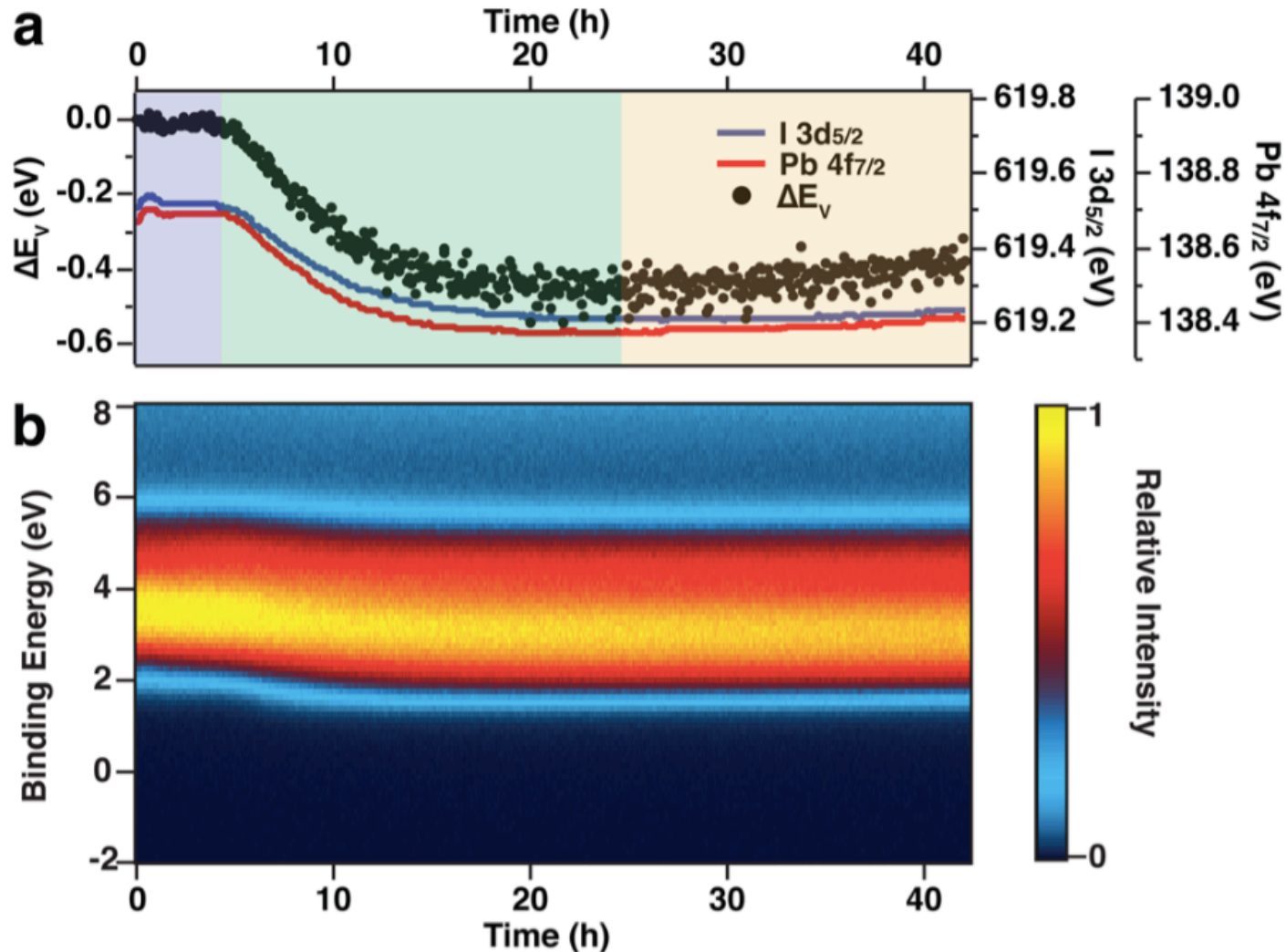
Spectral Decomposition



Valence Follows Molar Fraction



Initially Stable Properties



Neutral Ordered Defects

- XPS indicates CH_3NH_3 and I leaving simultaneously in pairs
- CIS tolerant to 1% defect density

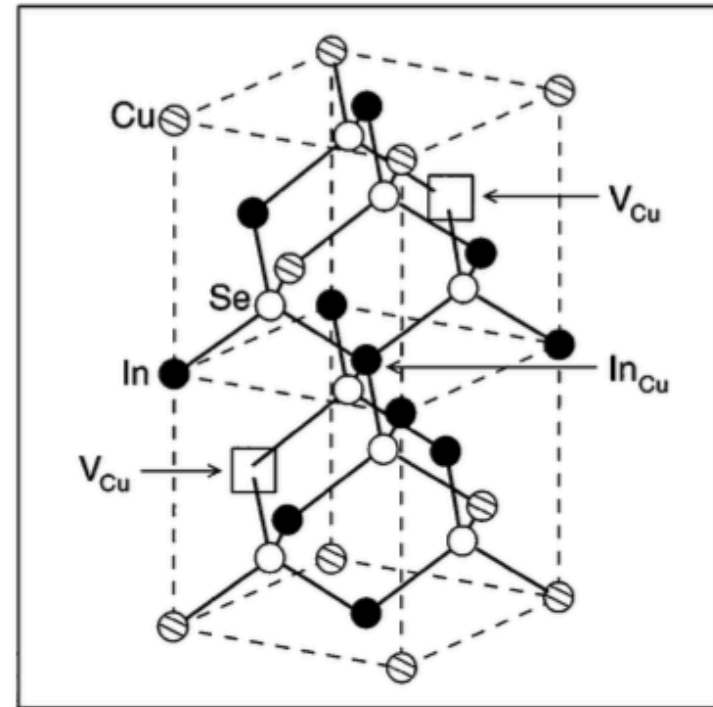
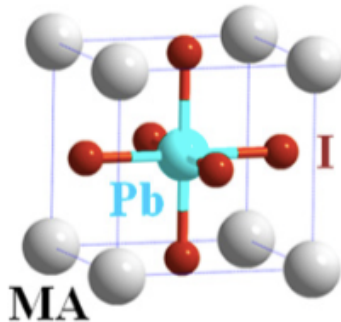
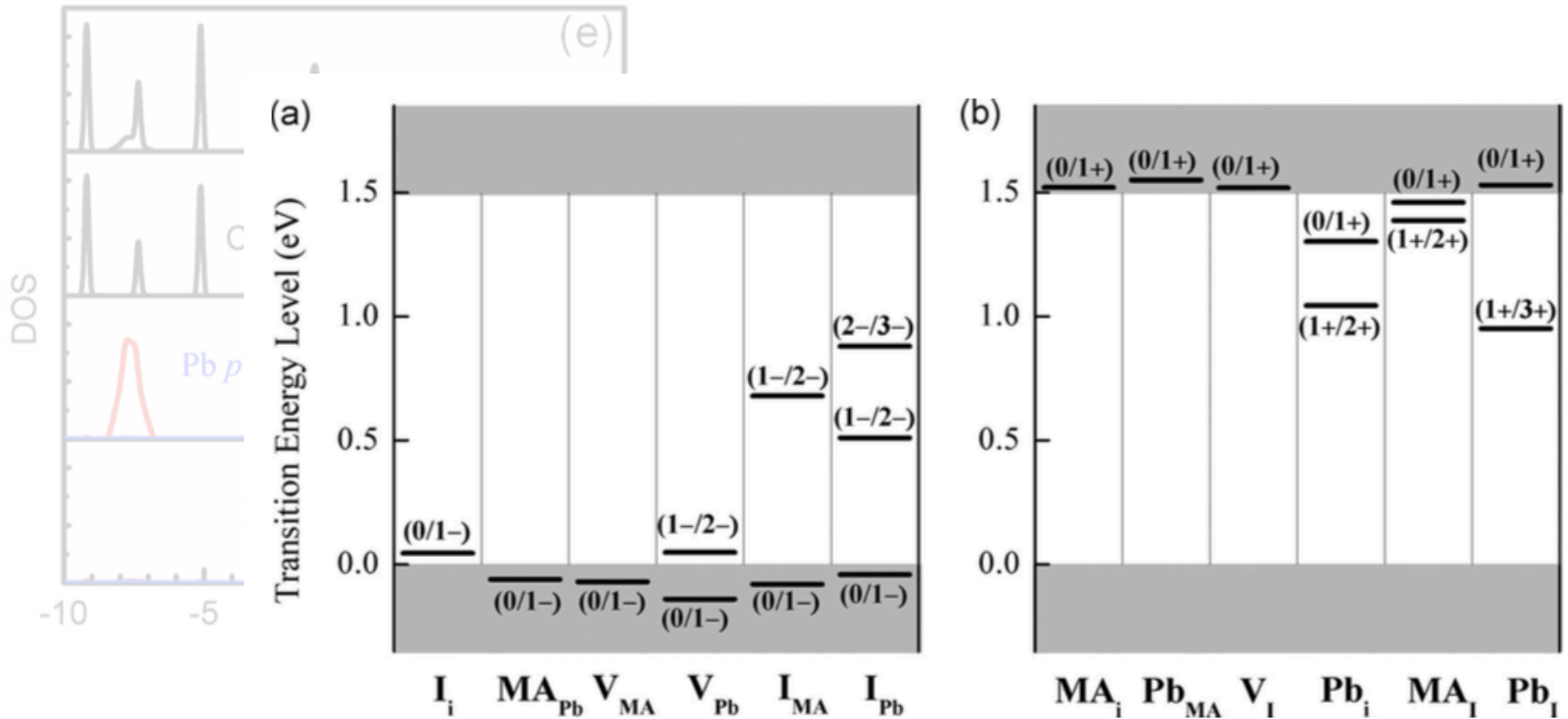


FIG. 3. The calculated structural model for the $(2V_{\text{Cu}}^- + \text{In}_{\text{Cu}}^{2+})$ defect pair.

- Zhang, S. B., Wei, S.-H. & Zunger, A. Stabilization of Ternary Compounds via Ordered Arrays of Defect Pairs. *Phys. Rev. Lett.* **78**, 4059–4062 (1997).
- Yin, W.-J., Shi, T. & Yan, Y. Unusual defect physics in $\text{CH}_3\text{NH}_3\text{PbI}_3$ perovskite solar cell absorber. *Appl. Phys. Lett.* **104**, 063903 (2014).

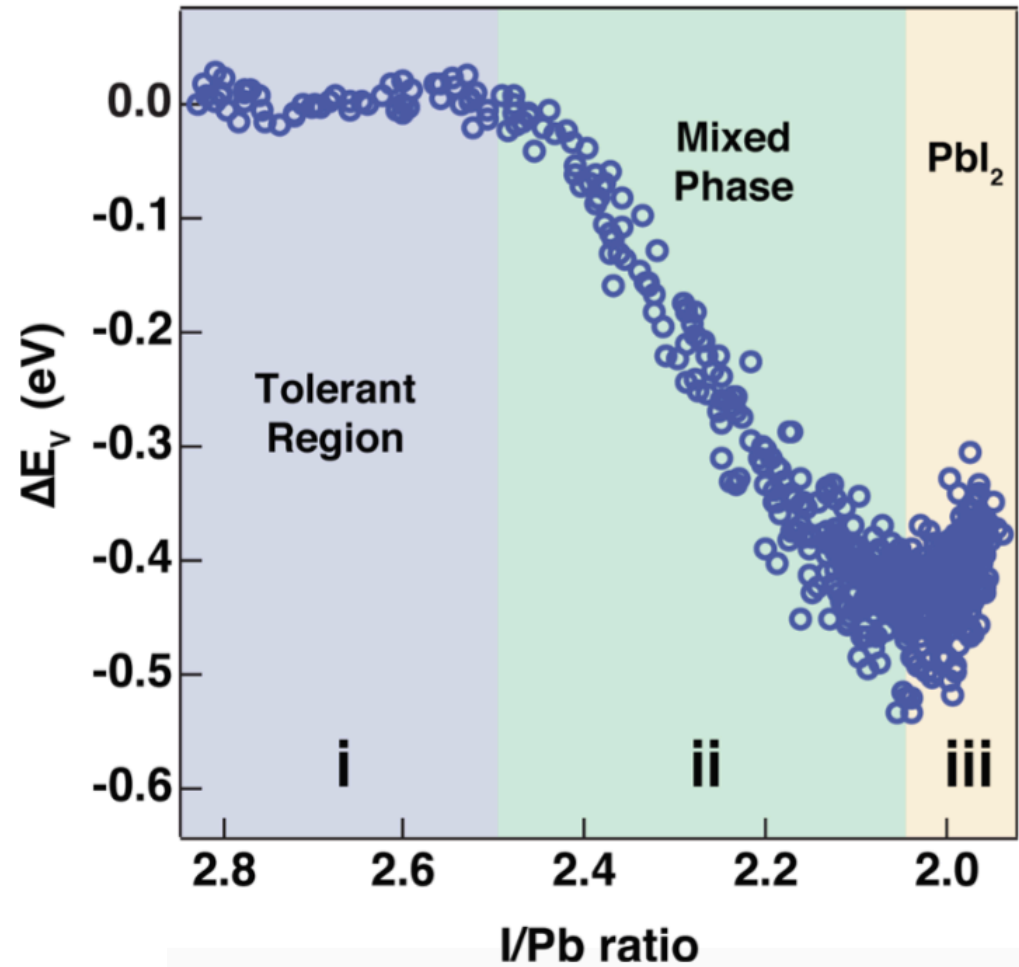
Defect Tolerance Predictions



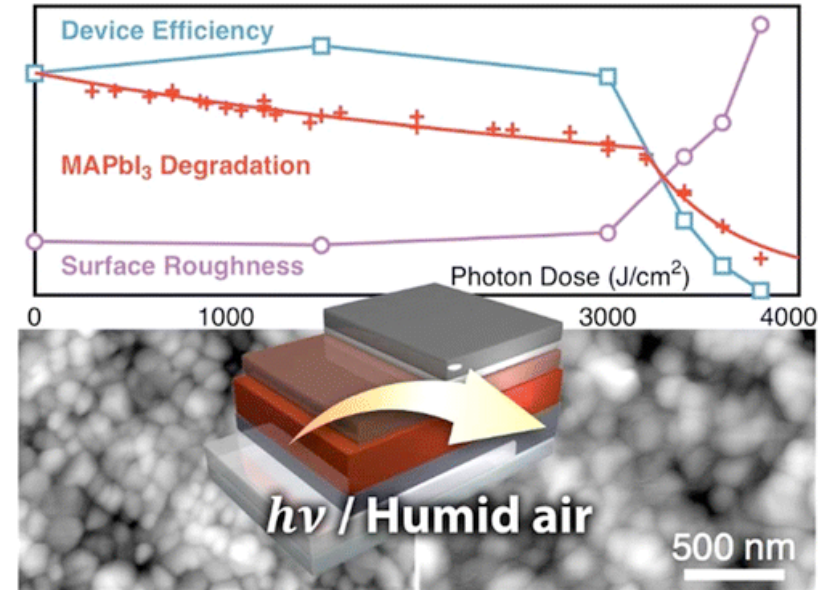
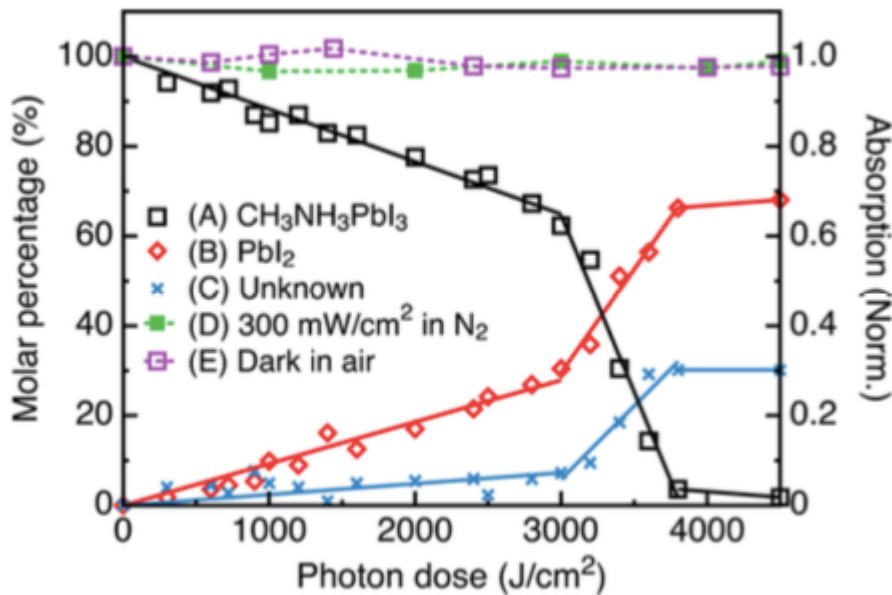
Yin, W.-J., Shi, T. & Yan, Y. Unusual defect physics in CH₃NH₃PbI₃ perovskite solar cell absorber. *Appl. Phys. Lett.* **104**, 063903 (2014).

CH₃NH₃PbI₃ Defect Tolerance

- Core levels for I and Pb track with E_v
- BE levels stable for I/Pb down to 2.5
- Defect formation appears to be paired V_{MA} + V_I
- Defect density corresponds to one defect per octahedron
- Tolerance up to 1/6 of I lattice sites!!!



Helps Explain Device Failure

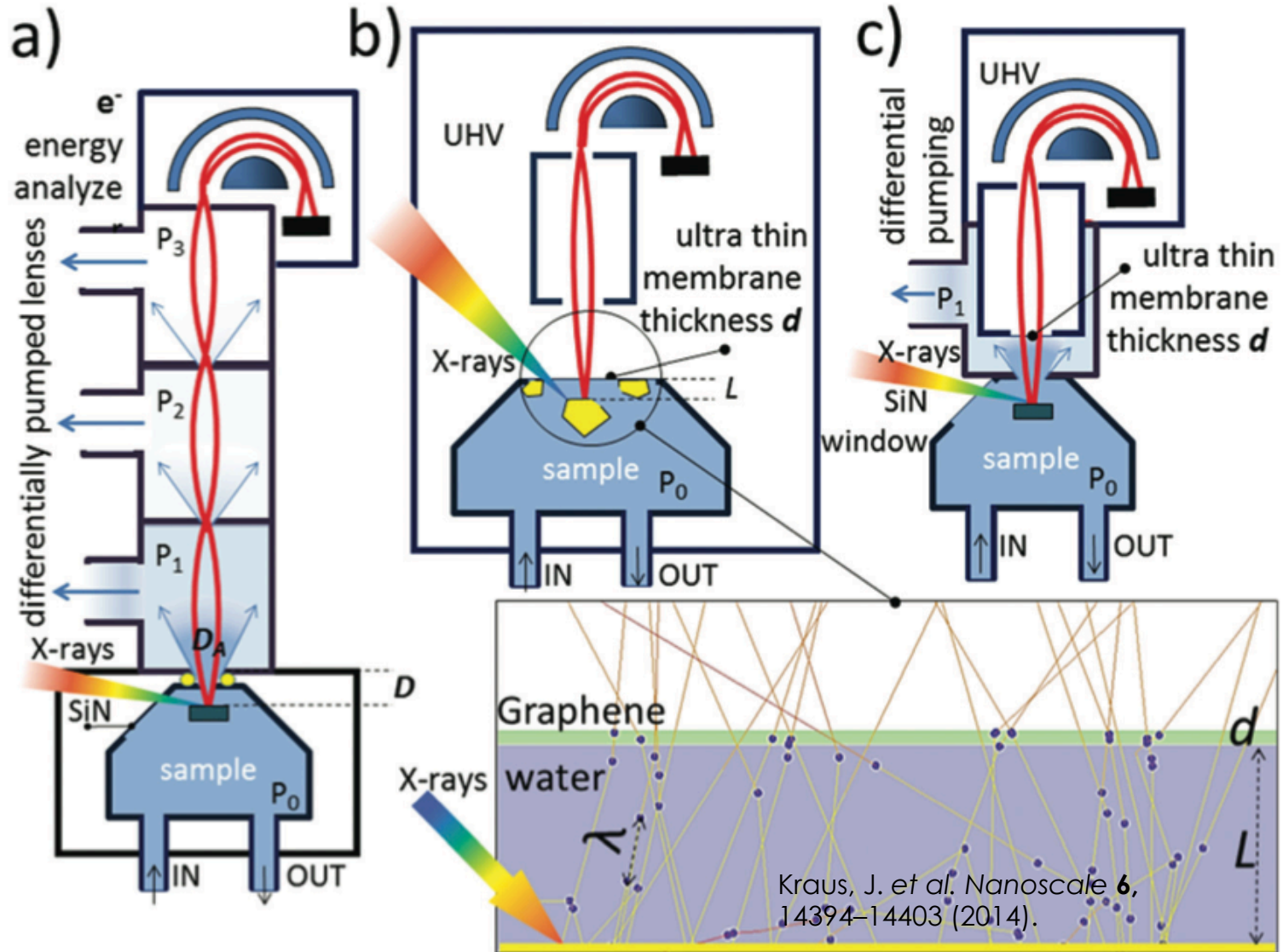


Matsumoto, F., Vorpahl, S. M., Banks, J. Q., Sengupta, E. & Ginger, D. S. Photodecomposition and Morphology Evolution of Organometal Halide Perovskite Solar Cells. *J. Phys. Chem. C* **119**, 20810–20816 (2015).

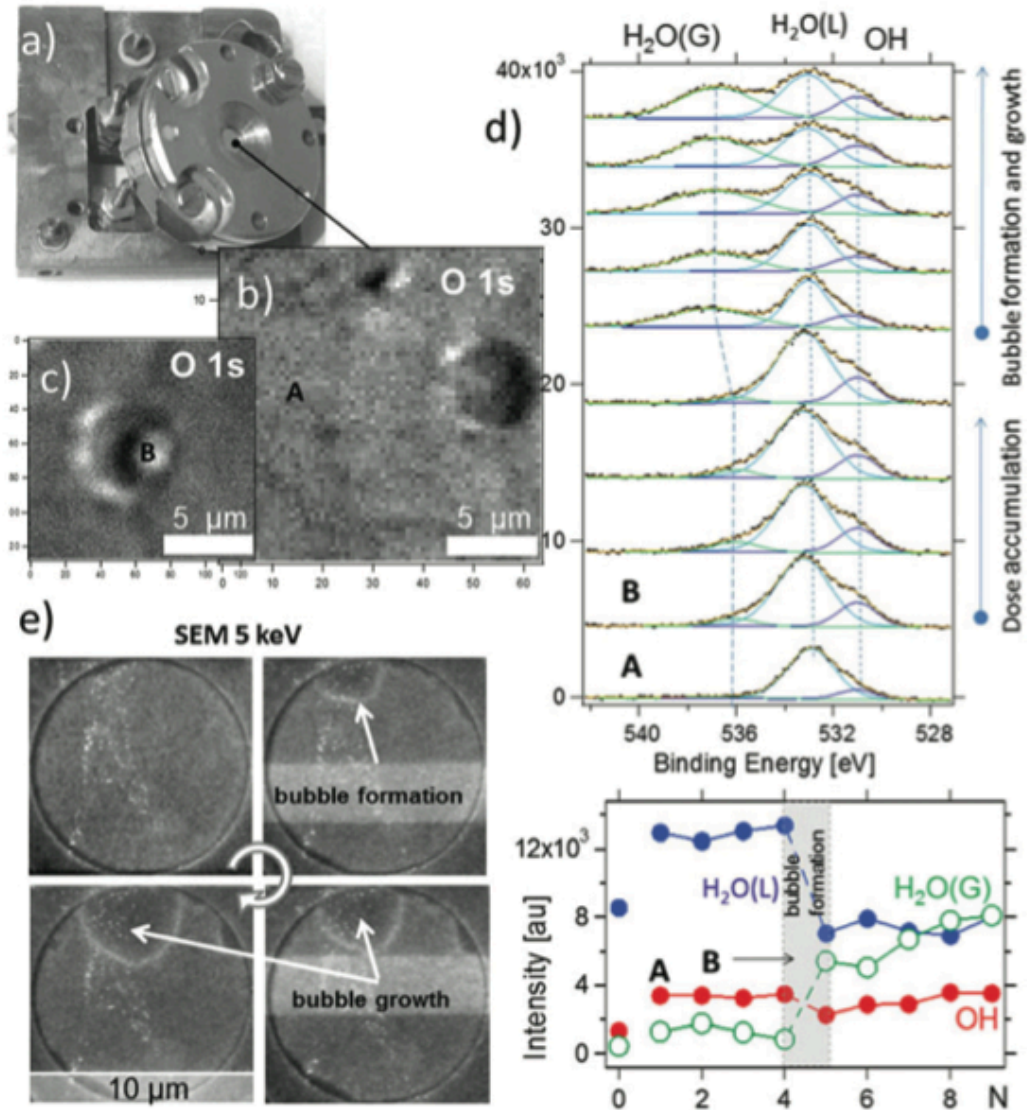
Emerging Areas in PES

- Ambient Pressure (APXPS)
- Operando
- Chemically Resolved Electrical Measurements (CREM)

Ambient Pressure PES

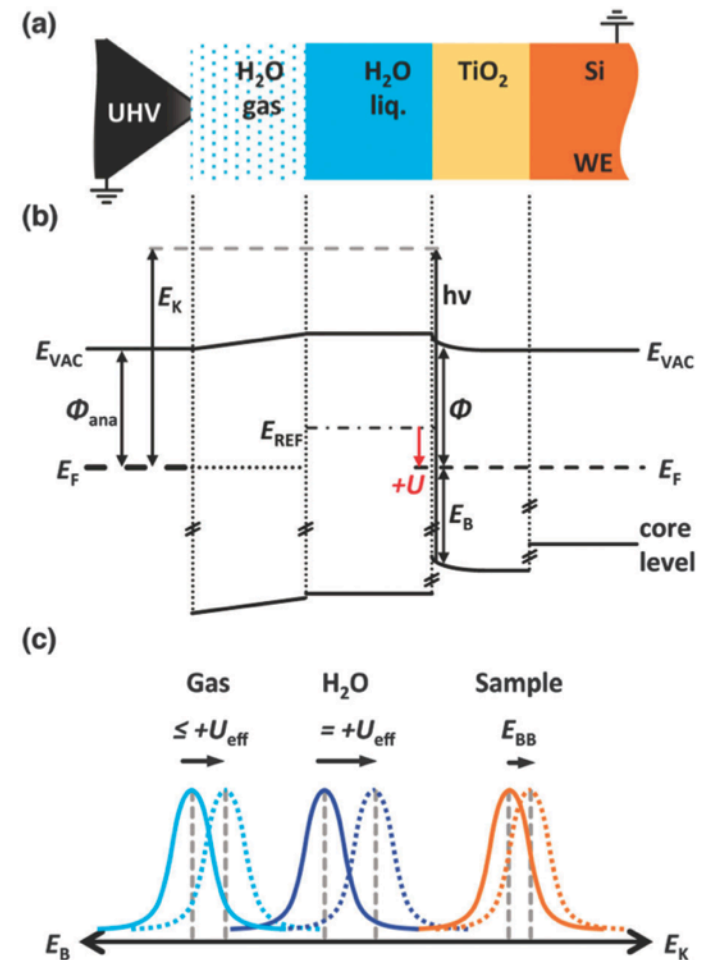
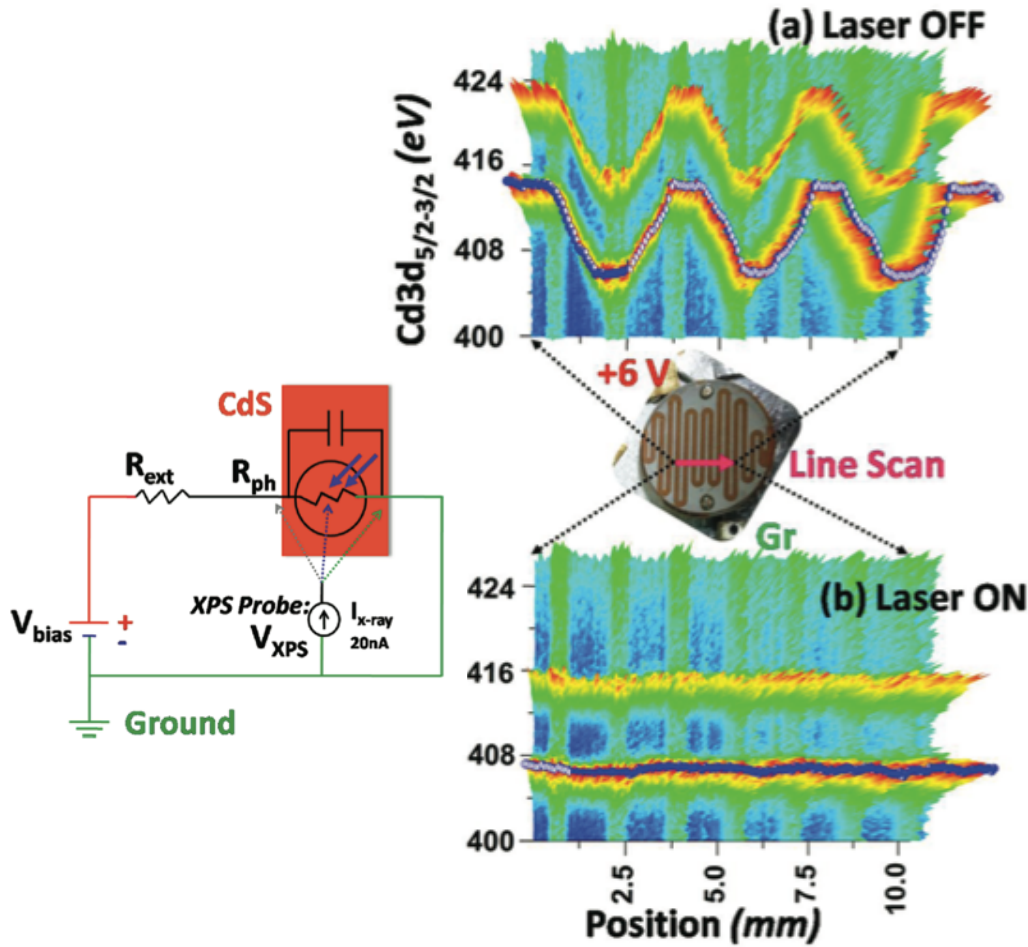


Ambient Pressure PES



Kraus, J. *et al.*
Nanoscale **6**, 14394–14403 (2014).

Operando PES

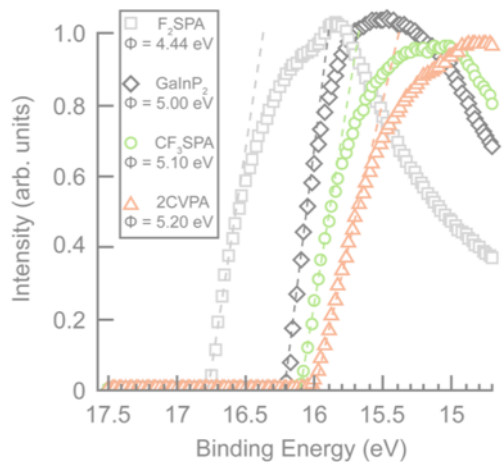


Sezen, H., Rockett, A. A. & Suzer, S. *Anal. Chem.* **84**, 2990–2994 (2012).

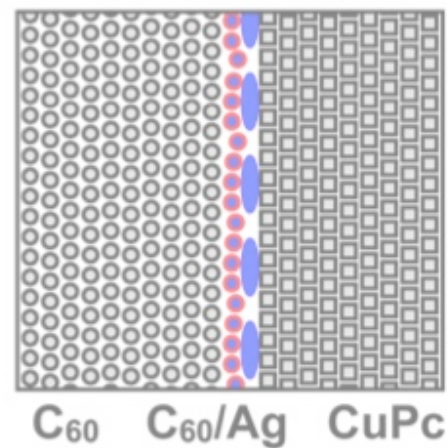
Lichterman, M. F. et al. *Energy Environ. Sci.* **8**, 2409–2416 (2015).

PES Research Topics

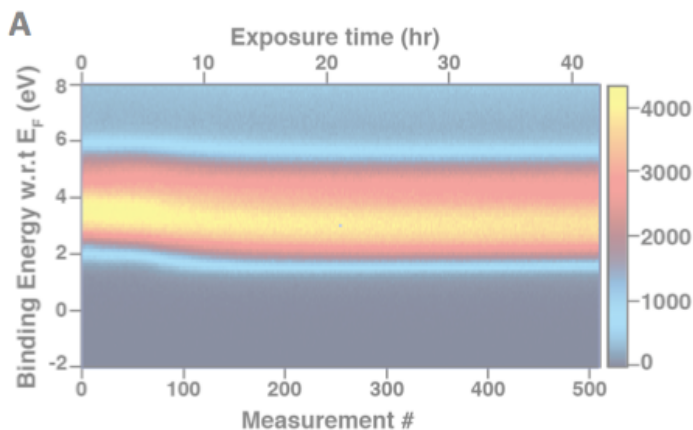
Dipole Studies



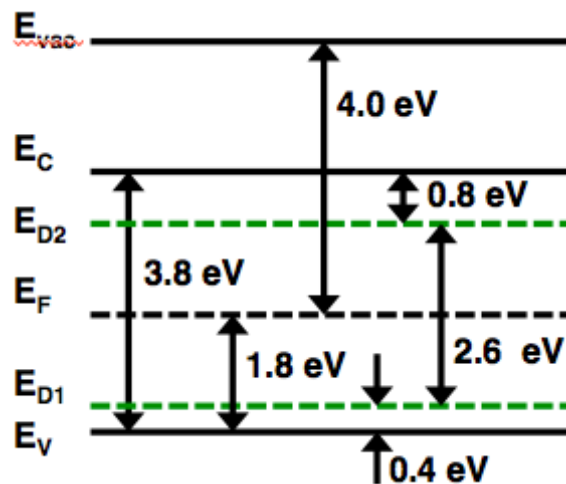
Nanostructured Interfaces



Phase Transformations



Defect Assessments



Chemically Resolved Electrical Measurements

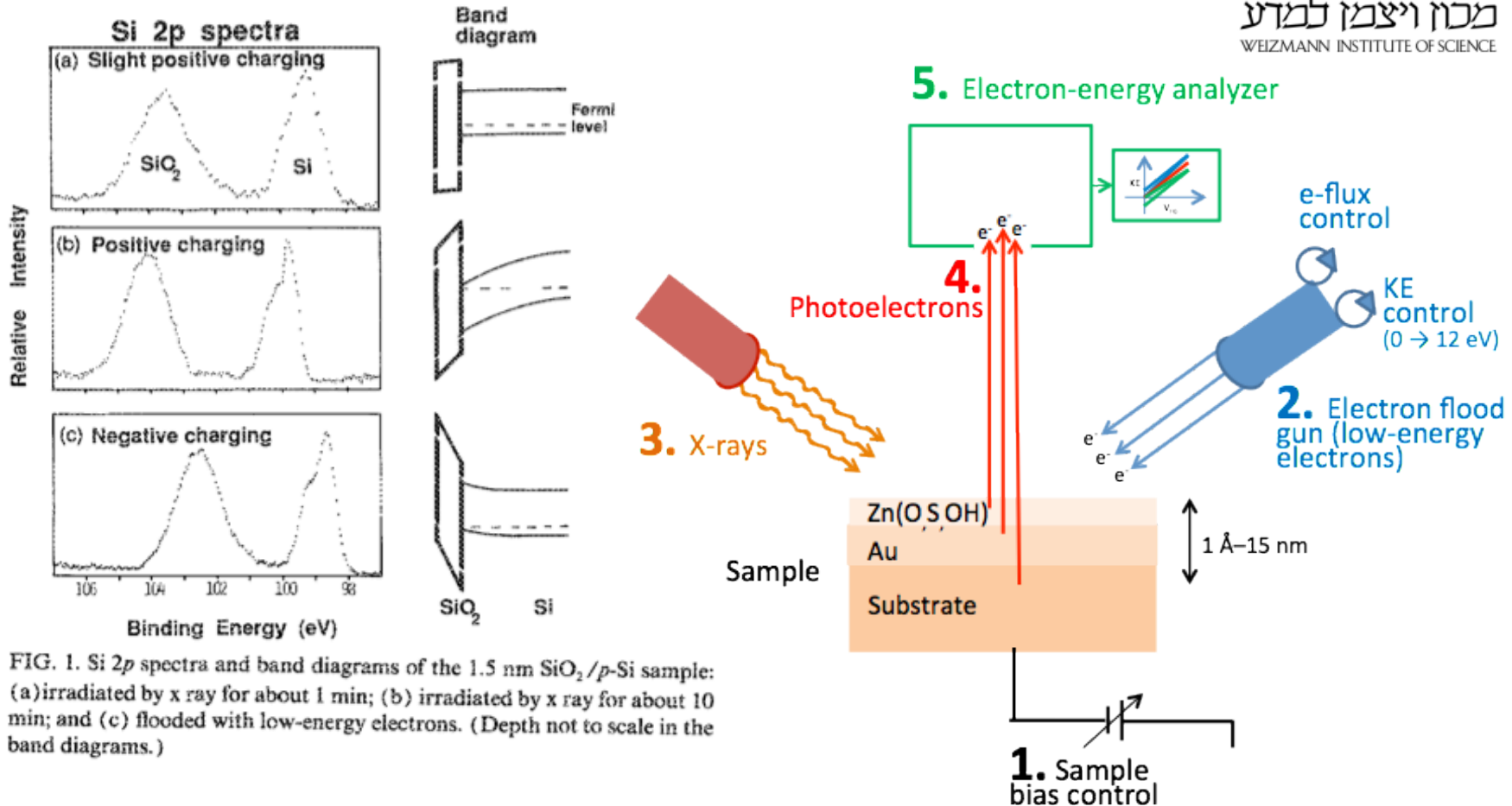
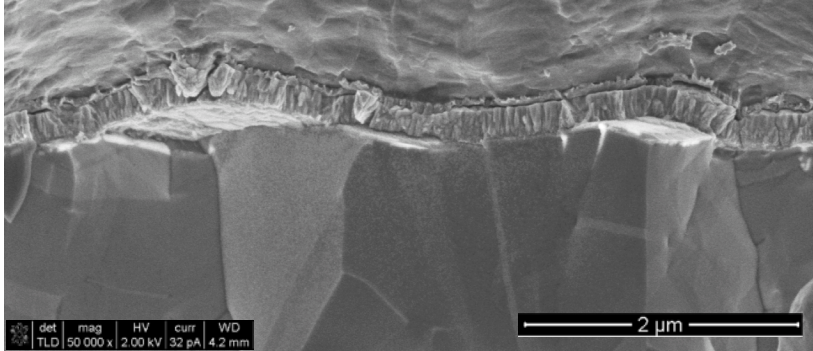


FIG. 1. Si 2p spectra and band diagrams of the 1.5 nm SiO₂/p-Si sample: (a) irradiated by x ray for about 1 min; (b) irradiated by x ray for about 10 min; and (c) flooded with low-energy electrons. (Depth not to scale in the band diagrams.)

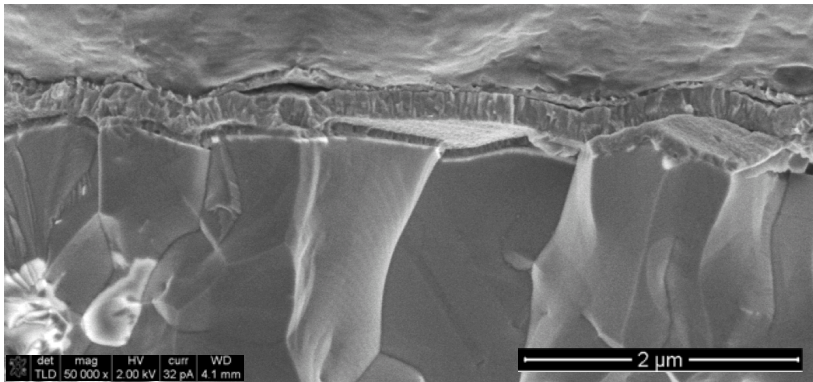
Lau, W. M. *Appl. Phys. Lett.* **54**, 338 (1989).
 Cohen, H. *Appl. Phys. Lett.* **85**, 1271–1273 (2004).
 Doron-Mor, I. et al. *Nature* **406**, 382–385 (2000).

$$E_{k,i} = h\nu - E_B^i + e\phi^i$$

Defects that enhance performance



CZTSe/**ZnOS**/i-ZnO/Al:ZnO/metal cleaved from device. CBD-ZnOS is visible and is physically central pn-junction formed between CZTSe and i-ZnO.



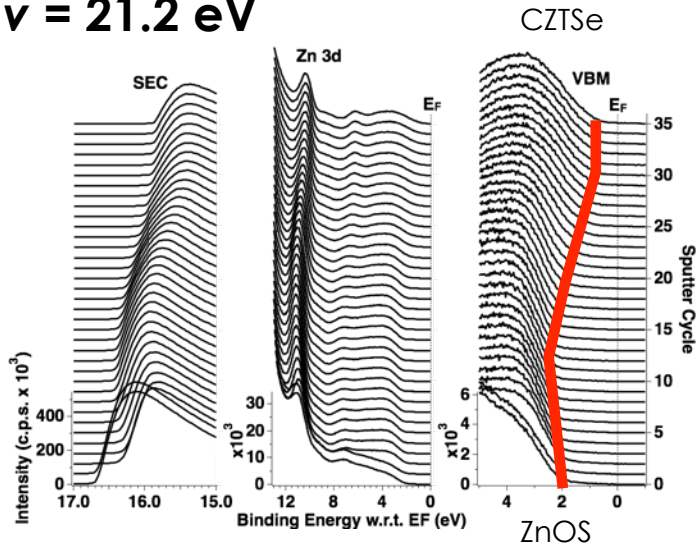
CZTSe/**CdS**/i-ZnO/Al:ZnO/metal cleaved from device. CBD-CdS operates differently than CBD-ZnOS by place exchange and results in very different electronic structure and solar cell operation.

CIS/ZnOS attained record 20.9% PCE - Osborne, Mark. "Solar Frontier produces record 20.9% CIS thin-film solar cell," *PVTech*, 02 April 2014.

Fraunhofer verified

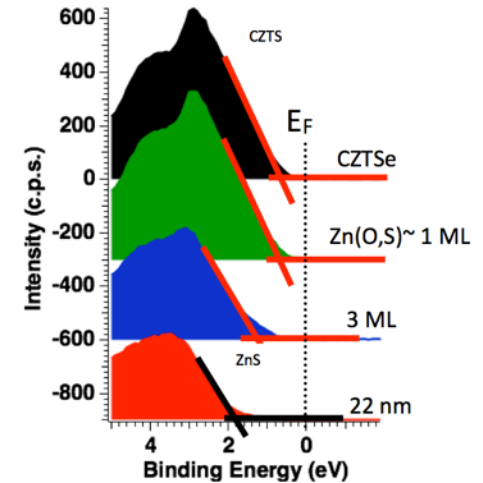
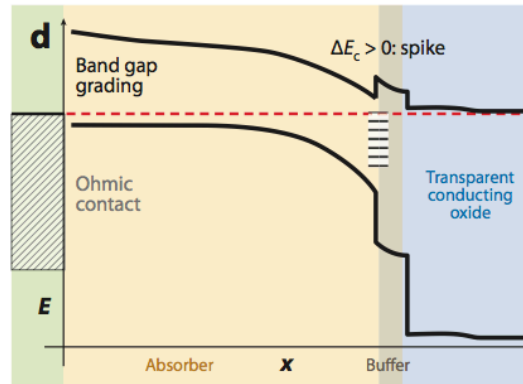
Huge Conduction Band Offset

$h\nu = 21.2 \text{ eV}$

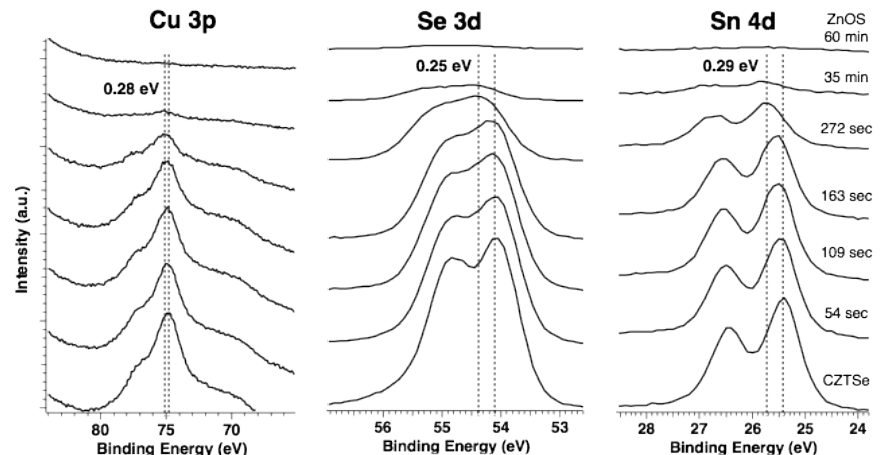
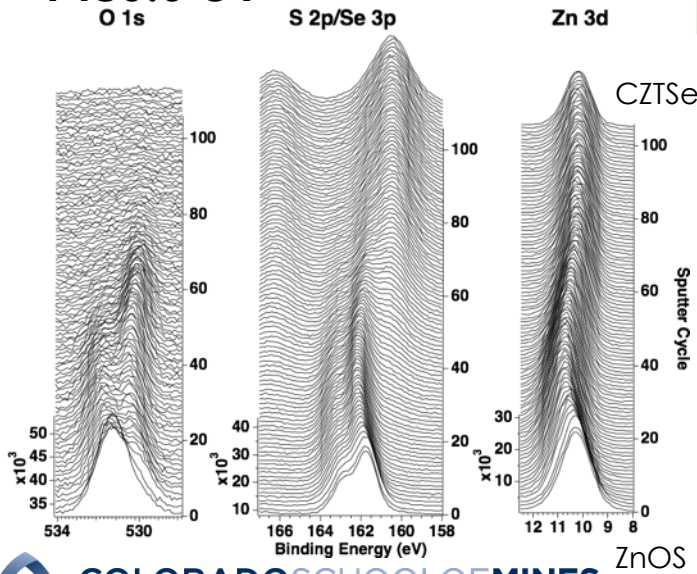


$$\Delta E_V = (E_{CL}^{ZnS} - E_{VBM}^{ZnS}) - (E_{CL}^{CZTS} - E_{VBM}^{CZTS}) - \Delta E_{CL,i} = -1.0 \text{ eV}$$

$$\Delta E_C = E_g^{ZnS} - E_g^{CZTS} + \Delta E_V = 1.6 \text{ eV}$$

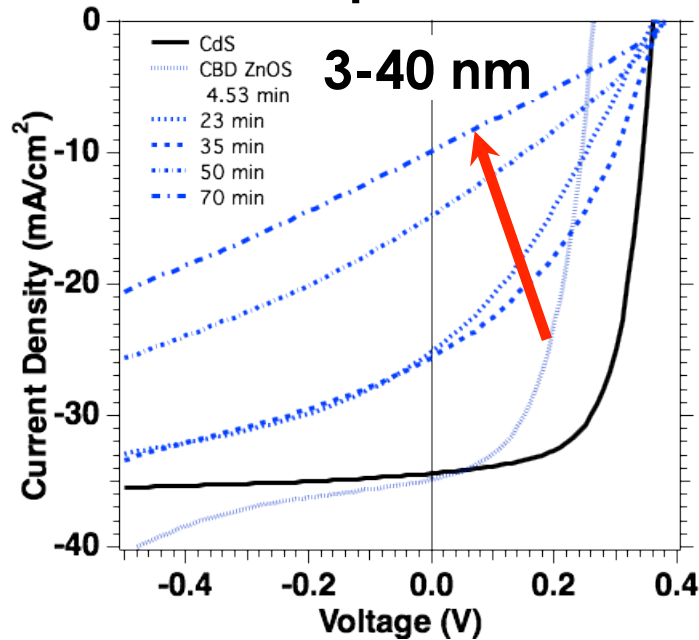


$h\nu = 1486.6 \text{ eV}$

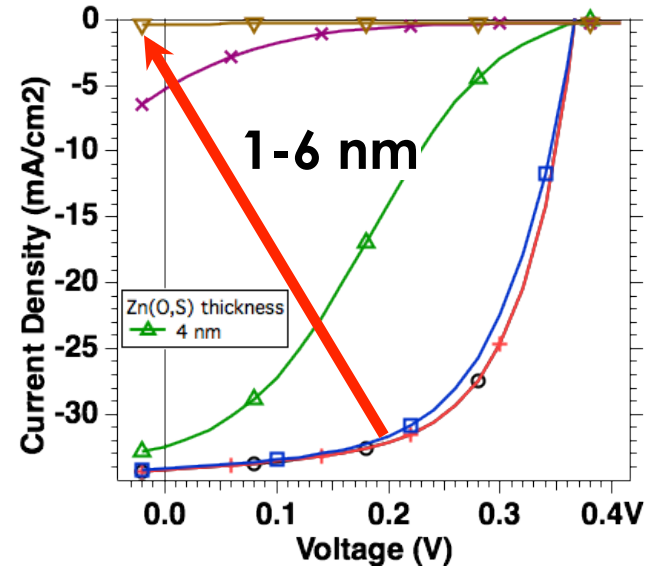


Unexpected Performance

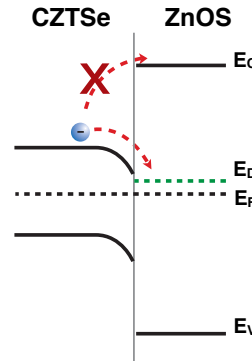
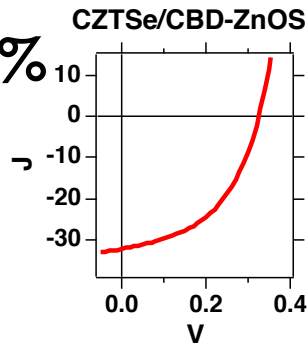
Experiment



Simulation



PCE_{max} = 5.1%

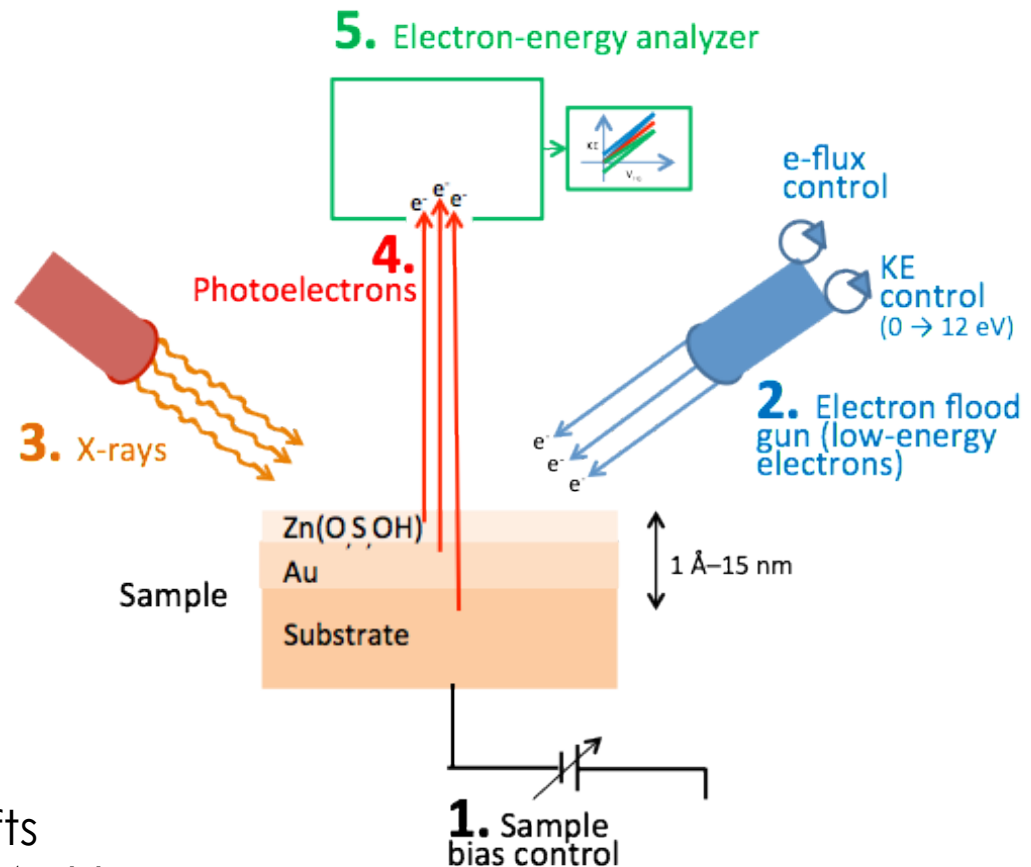
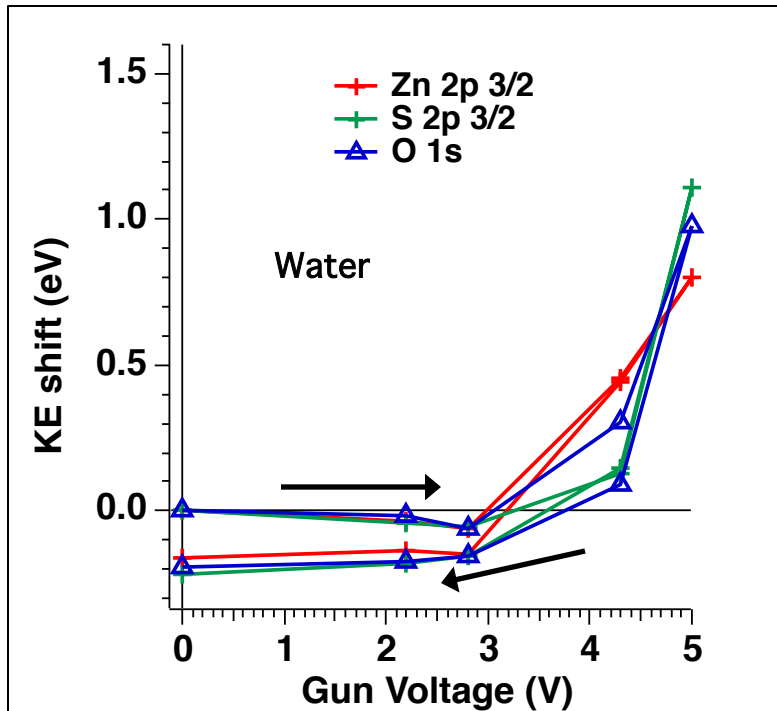


• Buffer Properties

- E_g = 3.8 eV
- CBO = 1.6 eV
- N_{ZnOS} = 10¹² - 10¹⁶ cm⁻³
- dielectric = 9
- One sun illumination

Chemically Resolved Electrical Measurements

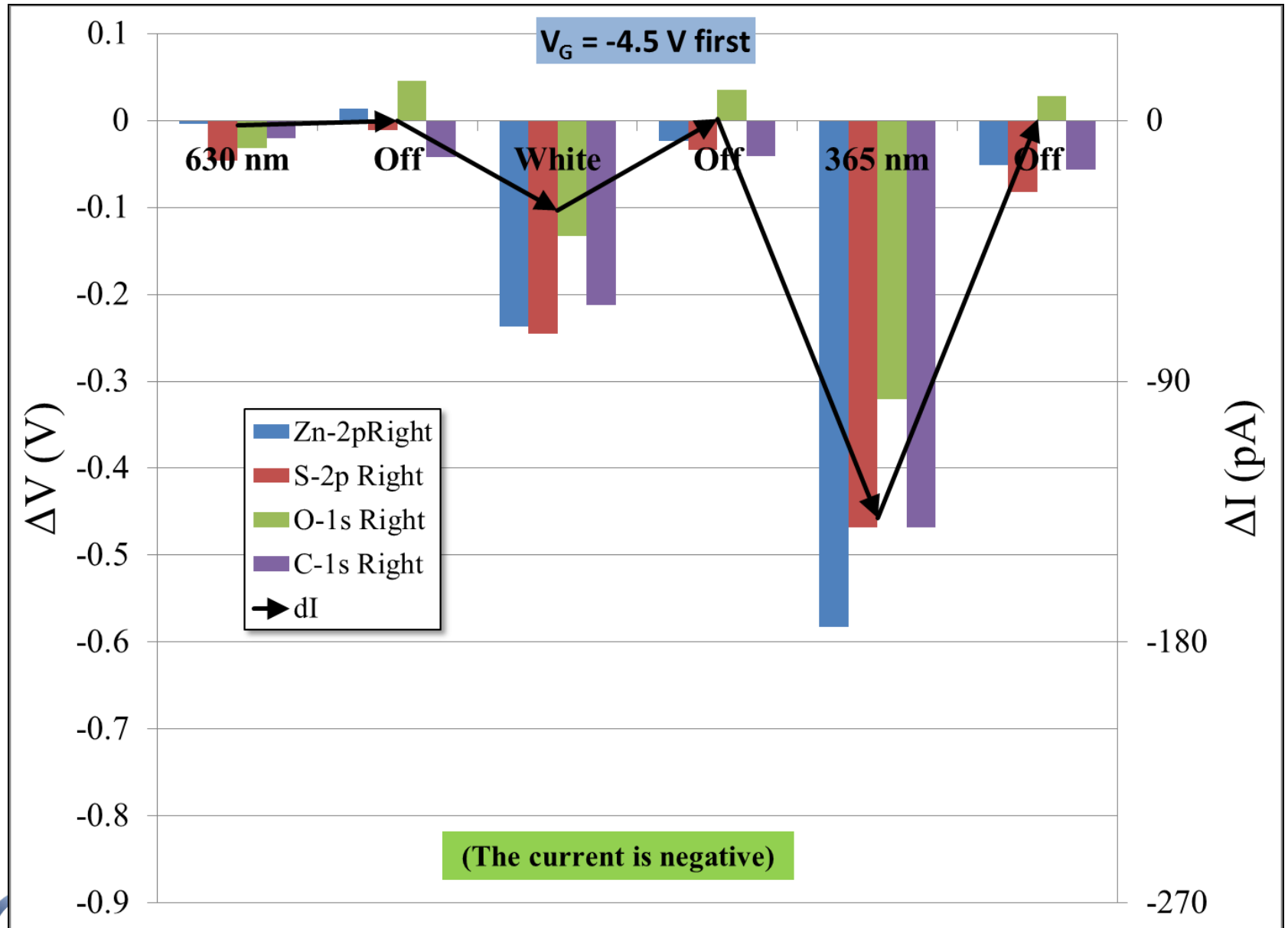
Electrical Loop



At each point, assess potential shifts with red 2.0 eV/white 2.8 eV/UV 3.4 eV

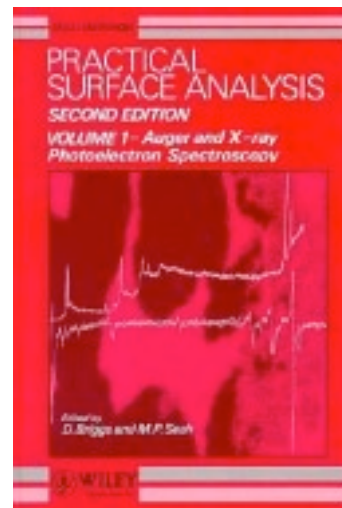
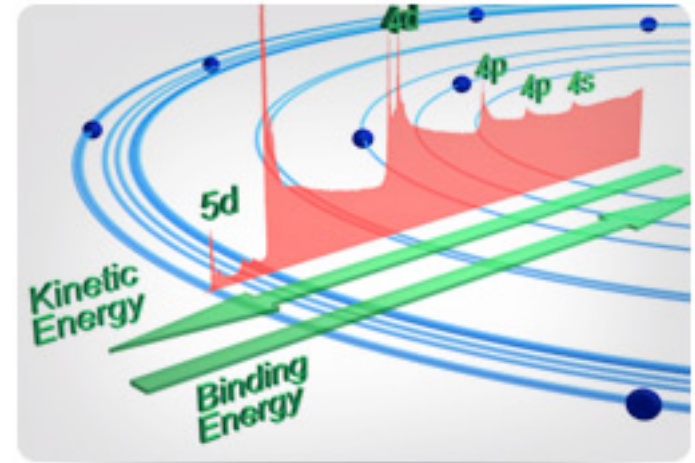
$$E_{k,i} = h\nu - E_B^i + e\phi^i$$

Light-CREM



Photoelectron Spectroscopy

- More Resources
 - Prof. Paul Chu Univ. Hong Kong
 - <http://slideplayer.com/slide/5052993/>
 - Ralph Claessen Univ. Wurzburg
 - <http://www.slideshare.net/nirupam12/photoelectron-spectroscopy-for-functional-oxides>
 - Textbook
 - Practical Surface Analysis by Briggs and Seah 1990



<http://xpssimplified.com/>

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Jordan Chesin
Philip Schulz
Steve Harvey
Craig Perkins
Glenn Teeter
Kai Zhu
Mengjin Yang

Erin Ratcliff
Gordon MacDonald
Kento Ou
Paul Lee
Neal Armstrong

Jens Meyer
Selina Olthof
Antoine Kahn

